



ACPL-352J

Infineon EconoPIM™ 3 IGBT Module EB1200-352J Evaluation Board

**Reference Manual
Version 1.0**

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Table of Contents

Chapter 1: About This Document	5
1.1 Scope and Purpose	5
1.2 Warnings	5
Chapter 2: Introduction	7
2.1 Design Features	8
2.2 Target Applications	8
Chapter 3: System Description	9
3.1 Key Specifications	9
3.2 Functional Block Diagram	9
3.3 Pin Assignments	12
3.3.1 Signal Interface	12
3.3.2 Power Interface	13
3.4 Mechanical Data	13
Chapter 4: Circuit Description	14
4.1 Auxiliary Power Management	14
4.2 Gate Driver Circuit	15
4.2.1 Gate Driver Circuit: Low-Voltage Side	15
4.2.2 Gate Driver Circuit: High-Voltage Side	16
4.2.3 Protection Features	16
4.2.4 Gate Resistor Consideration	18
4.3 DC Bus and Discharge Resistors	19
4.4 IGBT Current Measurement	20
4.5 Temperature Measurement	20
Chapter 5: Setup	22
5.1 Installation of the EB1200-352J	22
5.2 Evaluation of the EB1200-352J	22
Chapter 6: Typical Switching and DESAT Protection Characteristics	24
6.1 Typical Switching Losses	24
6.2 Typical Switching Waveforms	25
6.3 Typical DESAT Protection Performance	25
6.4 Typical GFAULT Performance	26
Appendix A: Schematics, Layout, and BOM	27
A.1 Schematics	28
A.2 Layout	34
A.3 BOM	39
A.4 Disclaimer	40

Revision History	41
Version 1.0, October 3, 2019	41

Chapter 1: About This Document

1.1 Scope and Purpose

This document describes how to use Broadcom® EB1200-352J evaluation board in a proper and safe way. The EB1200-352J evaluation board contains a power integrated module (PIM), which includes a three-phase diode bridge, a brake-chopper IGBT/diode, and a three-phase IGBT inverter, together with the gate driver circuit and DC bus capacitors. The voltage rating of the power module is 1200V. The evaluation board features an ACPL-352J isolated gate driver that drives IGBT switches and an ACPL-C87A isolated amplifier that measures the NTC temperature of the power module. The evaluation board supports the power integrated module (PIM) FP75R12KT4 and FP50R1200KT4G, but other PIMs with the same pin layout can be used as well. The integrated DC bus feature enables customers to evaluate the ACPL-352J isolated gate driver in conditions similar to actual applications, such as an industrial inverter.

The EB1200-352J board is a gate driver evaluation board and it is *not* intended to be used as the continuously operating inverter or as the part of some other series product. Thus, it is *not* intended to be used for the continuous inverter operation; it enables customers to evaluate driving and other characteristics of Broadcom's ACPL-352J gate drivers that are aimed for high-performance power electronics conversion systems. For the short time inverter operation evaluation, additional heatsinks must be mounted.

The EB1200-352J evaluation board can be either supplied with DC current by accessing DC bus terminals, or with AC current by using the input rectifier of the power module. In case an AC supply is used, ensure that an additional pre-charge circuit is added. Line chokes and a filter should also be placed. Additional boards with line input filters can be ordered separately.

If you need more information on the additional line filter board, or more specific data on the inverter operation evaluation, contact info@kinestas.com.

1.2 Warnings

The board operates at high voltages. Take special care to avoid the risk of injury and life endangering injuries. Consider, and take seriously, all of the following safety precautions when operating with this board:

- If the board is powered up, do not touch the board, especially exposed metal parts.
- Pay attention to the maximum ratings.
- Use of a protection cover made of insulating materials is mandatory.
- After powering off, wait at least 10 seconds for the DC bus capacitors to discharge, and check the DC bus voltage before touching the board.
- If board is used to drive a continuous load, the power module must be mounted on a heatsink. The board temperature may rise to high values. Therefore, any contact with the human body must be avoided.
- The board does *not* have a pre-charge circuit nor the EMC filter features. Thus, do *not* power-on the board directly from the three-phase AC grid if those features are not provided externally. For laboratory testing purposes, alternatives might be the usage of a three-phase autotransformer. Large inrush currents can cause failure and explosion of electrolytic capacitors, which can cause serious injuries.
- It is strongly recommended to place fuses at the input when powering the board.
- It is strongly recommended to connect a –DC_BUS terminal to ground prior to applying power to the board.
- Whenever a change in the test setup is done (for example, changing the probe position), turn off the DC bus and the +24V supply to avoid injuries and the destruction of the board.
- The board itself does not provide dead-time generation. The recommended minimal dead time is 5 μ s.

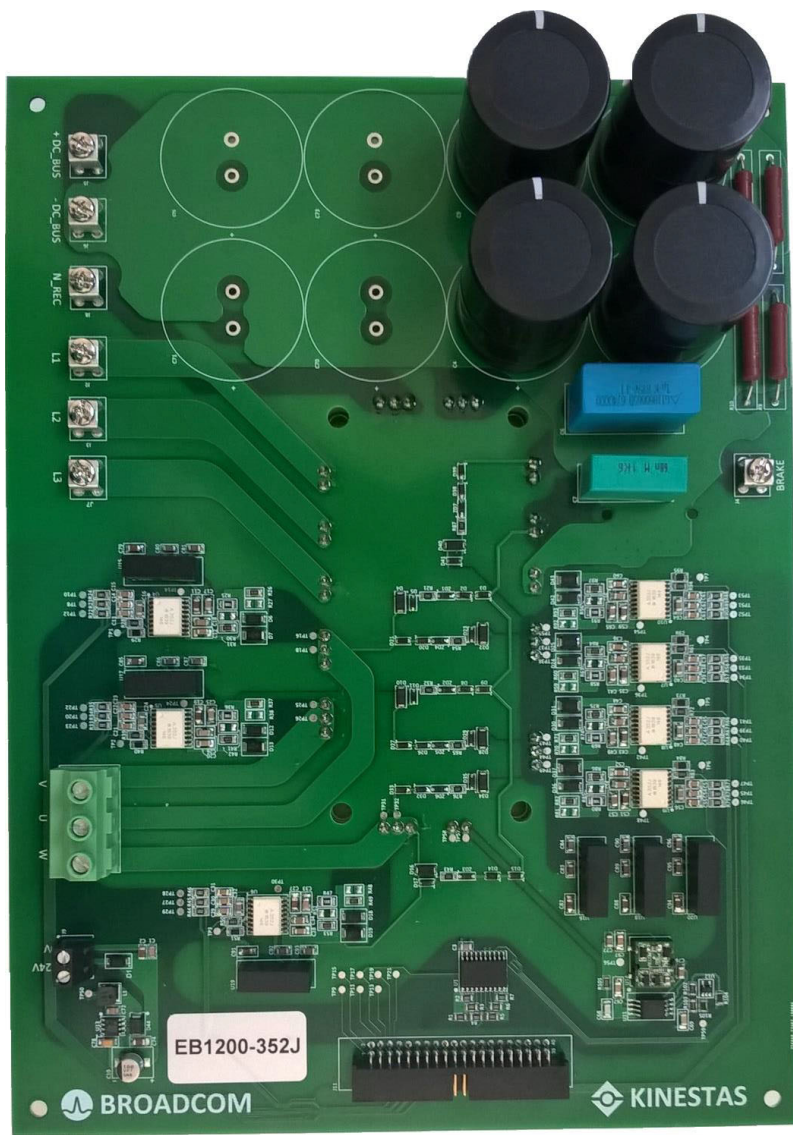
WARNING! Due to the technical requirements, high voltage components are used, and some of them could contain dangerous substances. Because the failure of such components can harm the user and even endanger the user's life, it is necessary to take all necessary precautions and safety measures prior to the evaluation of the EB1200-352J.

Chapter 2: Introduction

The EB1200-352J evaluation driver board with integrated DC bus, shown in [Figure 1](#), is developed to support Broadcom customers during their first steps in designing inverter applications with the ACPL-352J gate drivers. Board properties and typical performance are described in this reference manual. Information related to design is given with an aim to enable customers to copy and modify the design specifics according to their technical requirements and use it in their own designs (see [Section A.4, Disclaimer](#)).

The design is tested, as described in this document, at the temperature of 25°C, but it is not qualified regarding operation in the entire operating ambient temperature range of ACPL-352J, or its lifetime. The board is subjected to functional testing only. Electrical components used in this design are selected to be suitable for lead-free reflow soldering.

Figure 1: Evaluation Gate Driver Board EB1200-352J



2.1 Design Features

The EB1200-352J includes the following main features:

- Seven isolated ACPL-352J gate drivers with the following features:
 - Dual output drive to control turn-on and turn-off time independently
 - Overcurrent (OC) protection with configurable soft shutdown function
 - Gate status feedback
 - Undervoltage lock out (UVLO)
 - Active Miller clamp
 - Overcurrent fault and UVLO status feedback signal
- The ACPL-C87A optical amplifier enables isolated temperature measurement with the following features:
 - 0 to 2V nominal input range
 - 100-kHz bandwidth
 - 3V to 5.5V wide supply range for the output side
 - 15-kV/ μ s common-mode transient immunity
- Electrically and mechanically suitable for an 800V DC bus.
- EconoPIM™3 modules (FP75R12KT4/FP50R12KT4G).
- 24V/5V DC-DC power supply with current limit protection and thermal shutdown.
- Isolated power supplies for gate drivers.
- Access to PWM input signals.
- Access to the drivers' gate and overcurrent Fault and UVLO output signals for protection and control development purposes.
- An integrated DC bus with access to DC bus terminals.
- Access to the brake chopper terminal.
- Easy access to leg current using a Rogowski coil probe for switching characteristics evaluation.

2.2 Target Applications

The Broadcom ACPL-352J gate driver targets the following applications:

- Isolated IGBT/Power MOSFET gate drives
- Renewable energy applications
- AC and brushless DC motor drives
- Industrial inverters
- Switching power supplies

Chapter 3: System Description

This chapter provides the EB1200-352J specifications and functional description, interfaces, and mechanical details.

3.1 Key Specifications

Table 1 lists the absolute maximum ratings of the EB1200-352J. Note that Table 1 contains only key parameters. Constraints from ACPL-352J data sheet as well as specifications of other key components must be considered when the EB1200-352J is used.

Table 1: Absolute Maximum Ratings

Parameter	Values			Units	Note
	Min.	Typ.	Max.		
V_{dc+} to V_{dc-} when the DC bus supplied externally	—	600	800	V	Limited by the voltage overshoot during turn-off transient. DC bus capacitors voltage rating is 900V.
Input rectifier line to line RMS voltage	—	400	480	V	N_REC terminal should be shorted with -DC_BUS terminal, and one of the following conditions should be satisfied if the board is powered through three-phase AC lines (L1, L2, L3): <ul style="list-style-type: none"> ■ Pre-charge circuit is added externally. ■ Powering the board through an autotransformer enables smooth charging of the DC bus.
Brake chopper current	—	—	—	A	Limited by the power module ratings.
Inverter IGBT peak current	—	—	—	A	Limited by the power module ratings.
Continuous RMS current	—	—	—	A	Limited by the power module ratings and the heatsink characteristics.
V_{CC} input voltage	21.6	24	26.4	V	External DC input power supply for the digital circuitry.
PWM input logic level	0	3.3	5	V	External PWM inputs for the gate drivers; thresholds are defined in the ACPL-352J data sheet.
Fault output logic level	0	—	5	V	Logic output signal, refer to the ACPL-352J data sheet.
UVLO output logic level	0	—	5	V	Logic output signal, refer to the ACPL-352J data sheet.
GFAULT output logic level	0	—	5	V	Logic output signal, refer to the ACPL-352J data sheet.

3.2 Functional Block Diagram

Figure 2 shows the functional block diagram and Figure 3 shows the disposition of the functional blocks of the EB1200-352J gate evaluation board. In the middle of the system is a power integrated module (yellow), and its DC terminals are connected to a DC bus capacitor bank (blue). The DC bus can be supplied with an AC power source by using an integrated three-phase diode rectifier, or externally through the DC bus terminals. If a diode rectifier is used, the negative side of the diode rectifier (N_REC) and the negative side of the DC bus (-DC_BUS) must be shorted. The DC bus terminals as well as other power terminals are shown in grey in Figure 2. Low-voltage side connectors aimed for signal interface and power supply of digital side of ACPL-352J drivers are presented in green.

Figure 2: EB1200-352J Functional Block Diagram

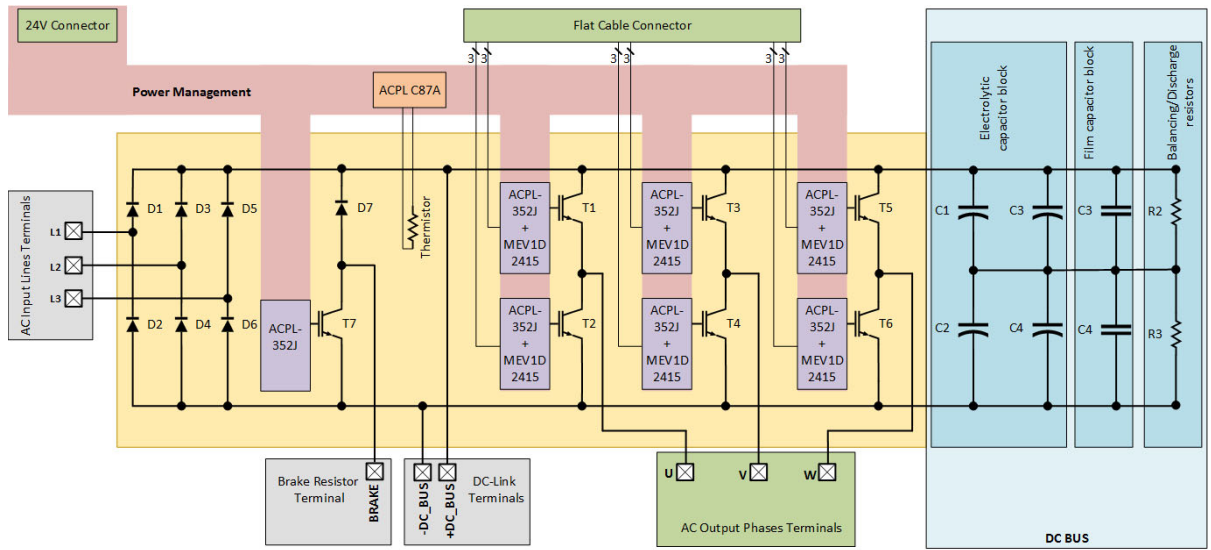
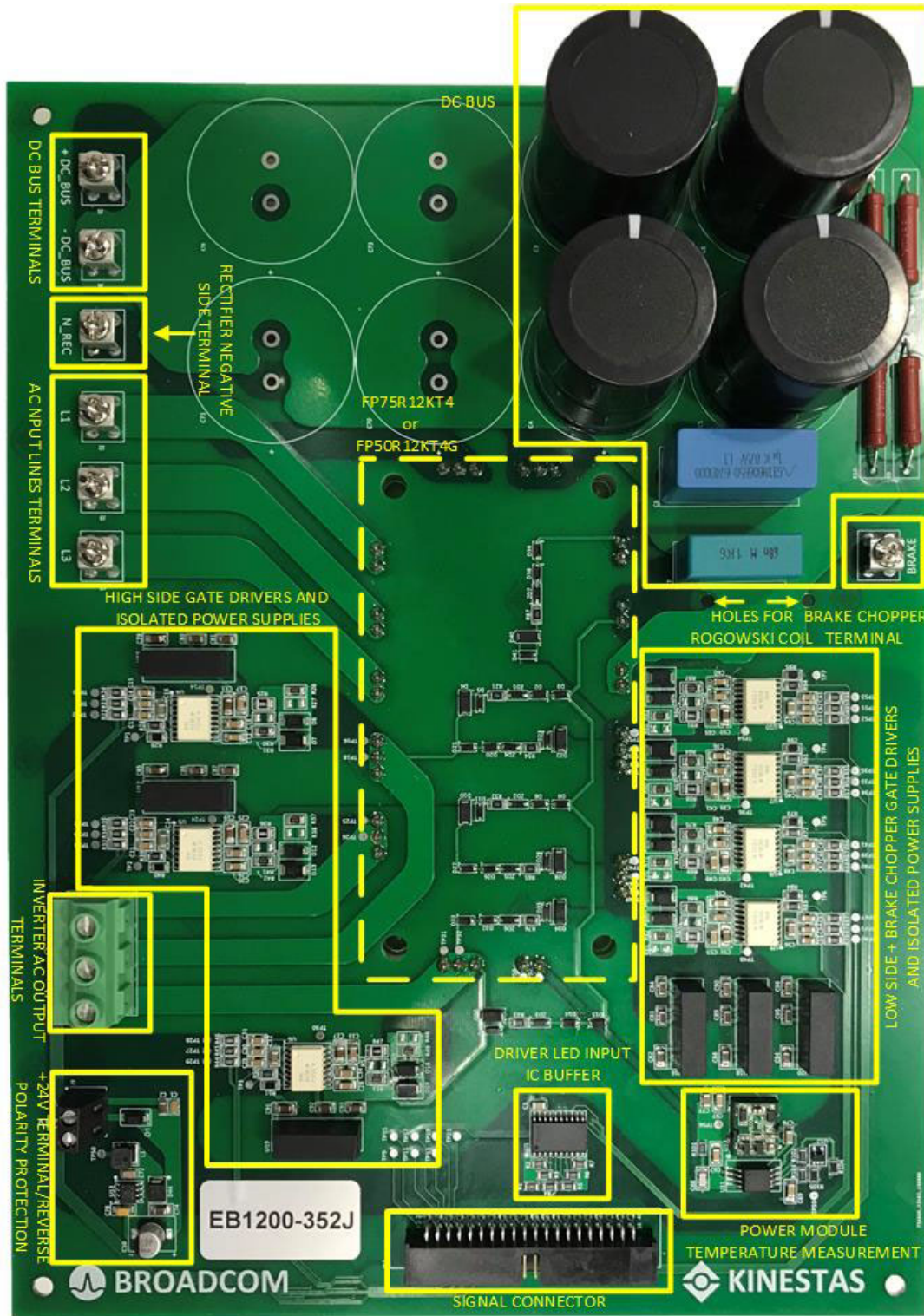


Figure 3: Functional Block Disposition of the EB1200-352J



3.3 Pin Assignments

This section describes the pin assignments of signal and power interface on the EB1200-352J. Part numbers and mechanical details of each connector can be found using manufacturer part numbers provided in [Section A.3, BOM](#).

3.3.1 Signal Interface

[Table 2](#) shows pin assignment for the signal connector J1. The schematic and layout of this connector are shown in [Appendix A, Schematics, Layout, and BOM](#).

Table 2: Pinout of Connector J1

Pin	Label	Function	Direction
1	PWM.U	PWM signal for high-side power switch in phase U	Input
2	PWM.X	PWM signal for low-side power switch in phase U	Input
3	PWM.V	PWM signal for high-side power switch in phase V	Input
4	PWM.Y	PWM signal for low-side power switch in phase V	Input
5	PWM.W	PWM signal for high-side power switch in phase W	Input
6	PWM.Z	PWM signal for low-side power switch in phase W	Input
7	PWM.B	PWM signal for brake power switch	Input
8	GND	Ground	Bidirectional
9	GND	Ground	Bidirectional
10	GND	Ground	Bidirectional
11	GND	Ground	Bidirectional
12	GND	Ground	Bidirectional
13	FAULT.B	Fault signal for brake power switch	Output
14	UVLO.B	UVLO signal for brake power switch	Output
15	FAULT.W	UVLO signal for high-side power switch in phase W	Output
16	UVLO.W	Fault signal for high side power switch in phase W	Output
17	FAULT.V	UVLO signal for high-side power switch in phase V	Output
18	UVLO.V	Fault signal for high-side power switch in phase V	Output
19	FAULT.U	UVLO signal for high-side power switch in phase U	Output
20	UVLO.U	Fault signal for high-side power switch in phase U	Output
21	FAULT.X	UVLO signal for low-side power switch in phase U	Output
22	UVLO.X	Fault signal for low side power switch in phase U	Output
23	FAULT.Y	UVLO signal for low-side power switch in phase V	Output
24	UVLO.Y	Fault signal for low-side power switch in phase V	Output
25	FAULT.Z	UVLO signal for low-side power switch in phase W	Output
26	UVLO.Z	Fault signal for low side power switch in phase W	Output
27	GND	Ground	Bidirectional
28	GND	Ground	Bidirectional
29	GND	Ground	Bidirectional
30	TEMP	Isolated temperature measurement signal	Output
31	GFAULT.U	GFAULT signal for high-side power switch in phase U	Output
32	GFAULT.X	GFAULT signal for low-side power switch in phase U	Output
33	GFAULT.V	GFAULT signal for high-side power switch in phase V	Output
34	GFAULT.Y	GFAULT signal for low-side power switch in phase V	Output

Table 2: Pinout of Connector J1 (Continued)

Pin	Label	Function	Direction
35	GFAULT.W	GFAULT signal for high-side power switch in phase W	Output
36	GFAULT.Z	GFAULT signal for low-side power switch in phase B	Output
37	GFAULT.B	Fault signal for brake power switch	Output
38	GND	Ground	Bidirectional
39	GND	Ground	Bidirectional
40	GND	Ground	Bidirectional

3.3.2 Power Interface

Description of the power terminals are provided in [Table 3](#).

Table 3: Power Interface, Connectors Description

Label	Connector Description	Value
+DC_BUS	DC bus positive rail input	M4 screw terminal
-DC_BUS	DC bus negative rail input	
N_REC	Negative diode rectifier output rail	
BRAKE	Brake chopper IGBT – collector	
L1, L2, L3	Diode rectifier phase inputs	
U, V, W	Inverter phases	PCB screw terminal
0 V, 24 V	Isolated power supply input for digital circuitry	PM5.08/2/90, 26 AWG, 14 AWG

3.4 Mechanical Data

[Table 4](#) provides a complete list of the mechanical data.

Table 4: Mechanical Data of the EB1200-352J

Description	Value
Number of layers	4
PCB copper thickness	70 µm – top and bottom layer 35 µm – inner layers
PCB Insulating material	FR4
Board weight without PIM	610 g
Board length	292 mm
Board width	217 mm
Board height	48.6 mm
PCB thickness	1.6 mm

Chapter 4: Circuit Description

This chapter provides an in-depth insight of the features of the EB1200-352J gate driver evaluation board.

4.1 Auxiliary Power Management

Figure 4 shows the auxiliary power management block diagram of the EB1200-352J, and Figure 5 shows the EB1200-352J power supply circuitry. The evaluation board is supplied from an external +24V source. The main 24V/5V power supply, based on LM2674 DC-DC switching regulator, is shown in Figure 5a. The +5V output of this power supply is used to supply the ACPL-352J gate drivers and the ACPL-C87A voltage sensor low-voltage side. An isolated 5V/5V voltage regulator, R1SX-0505-R, provides an isolated 5V for the ACPL-C87A high-voltage side, as shown in Figure 5b. The EB1200-352J has six isolated power supplies 24V/+15V/-15V, which provide separated +15V and -15V for each gate driver high-voltage side. This circuitry is shown in Figure 6. Note that the ACPL -352J driver dedicated to drive the brake chopper IGBT shares a secondary side power supply with the ACPL-352J that drives low-side power switch.

Figure 4: Power Management Block Diagram

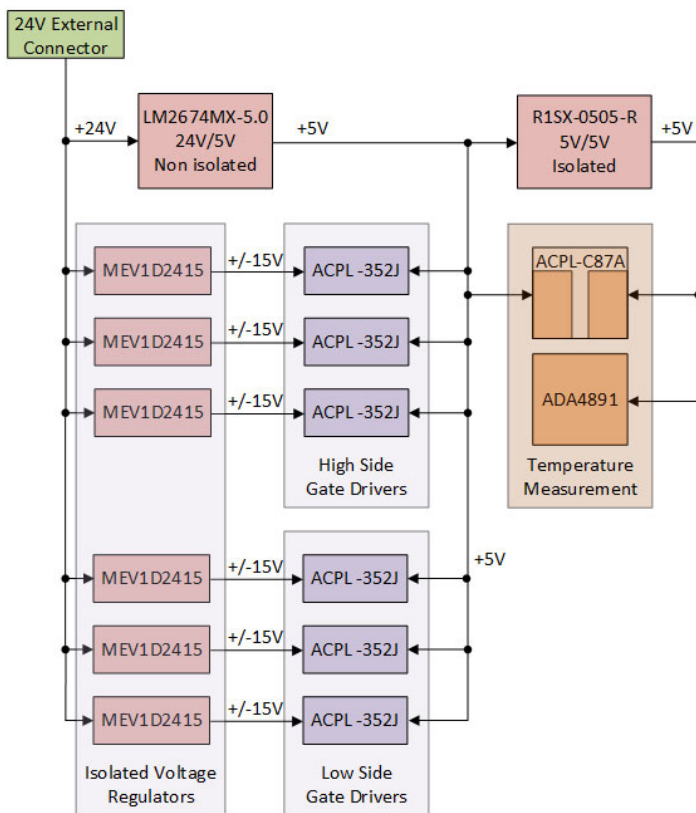


Figure 5: (a) 24V/5V Power Supply of the EB1200-352J Board, and (b) the Isolated 5V/5V Power Supply

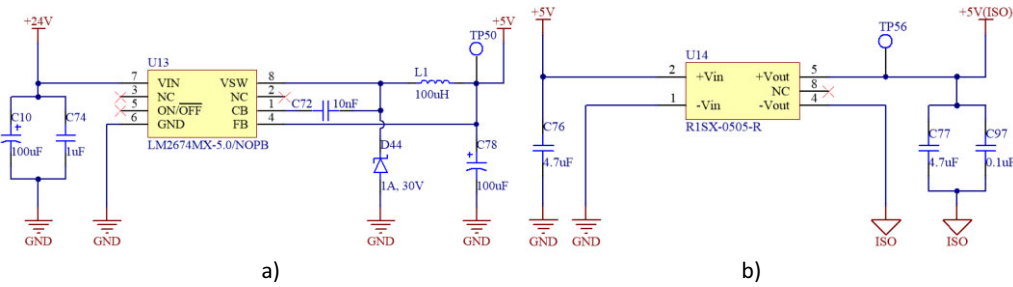
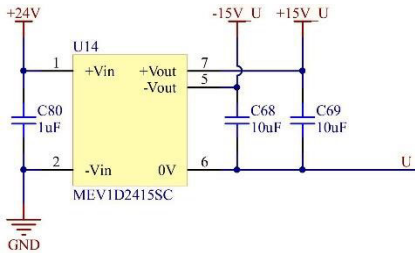


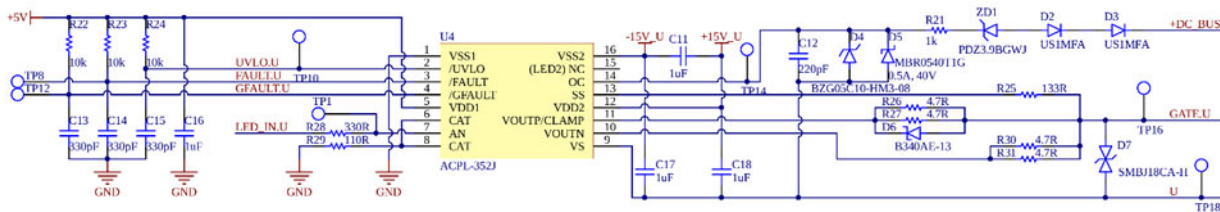
Figure 6: 24V/+15V/-15V Isolated Gate Driver High-Voltage Side Power Supply



4.2 Gate Driver Circuit

The used optocoupler-based IGBT gate drivers, ACPL-352J, feature fast signal propagation, desaturation detection, soft shutdown protection, active clamping, and fault feedback. Figure 7 shows the both the low-voltage and high-voltage side gate driver circuit.

Figure 7: Isolated Gate Drive Based on ACPL-352J

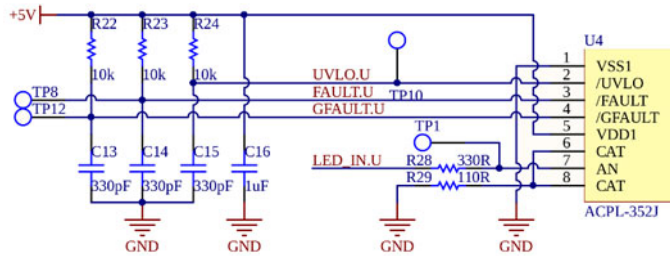


4.2.1 Gate Driver Circuit: Low-Voltage Side

Figure 8 shows the low-voltage (digital) side of the driver circuitry. The low-voltage side of the driver is supplied with +5V on the VCC1 pin. The UVLO, FAULT, and GFAULT signals are pulled up to +5V with 10-kΩ resistors. These signals are normally active high when no fault is present. Two 330-pF capacitors are added as a support for these signals according to the data sheet. The two resistors 330Ω and 110Ω are connected to input LED's anode and cathode to help in equalizing the common mode voltage changes at the anode and cathode and give high CMR performance. The input LED signal that is interfacing with the controller is amplified with an IC buffer.

ATTENTION: Signals dedicated for high-side and low-side drivers, in one inverter leg, need to have proper dead time. The board itself does not provide dead-time generation. The recommended minimal dead time is 5 μs.

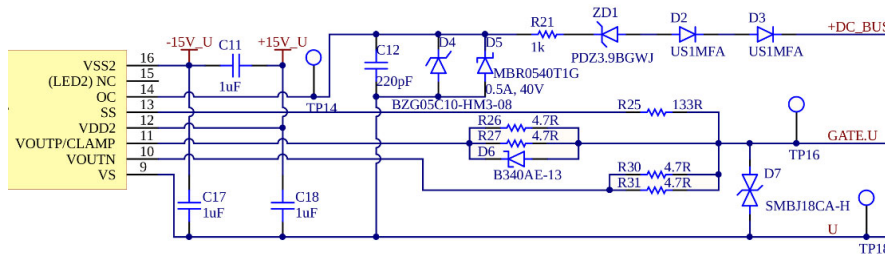
Figure 8: Isolated Gate Driver ACPL-352J Primary Side



4.2.2 Gate Driver Circuit: High-Voltage Side

Figure 9 shows the high-voltage side of the gate driver circuitry. It consists of bypass capacitors, an OC protection circuit, and a driver output stage. The OC protection circuit is described in Section 4.2.3, Protection Features. The output stage of the ACPL-352J is supplied with +15V and -15V. These voltages are supported with 1-μF bypass capacitors that provide large transient currents that occur during switching transition. The HV blocking diodes, resistor 1 kΩ, and 220-pF blanking capacitor are used to protect the OC pin and prevent false fault detection. During overcurrent fault conditions, the IGBT is soft shut down through the SS pin and the rate of shutdown can be adjusted by resistor R25. The gate resistor serves to limit the gate current and indirectly control the IGBT switching times. Schottky diode D6 is used together with the CLAMP function to shunt parasitic IGBT Miller current during the off cycle. The status of the IGBT gate voltage is monitored by output pins VOUTP and VOUTN. The GFAULT output goes low when the gate voltage does not correspond to the LED input logic. Selection criteria for the gate resistors is described in Section 4.5, Temperature Measurement. There are two positions for VOUTP and two positions for VOUTN on every gate driver where the gate resistor can be placed. This enables the user to quickly adjust the gate resistor and evaluate switching characteristics of the IGBT. Equivalent turn-on gate resistance is defined by two parallel resistors (R26 and R27 in Figure 9) while the turn-off gate resistance is defined by other two resistors connected in parallel (R30 and R31). In case of a faulty power supply or unexpected overvoltage, the TVS diode is placed between the gate and the emitter of the IGBT, and it ensures that no damage is done to the IGBT gate structure. Voltage is limited to ± 18V.

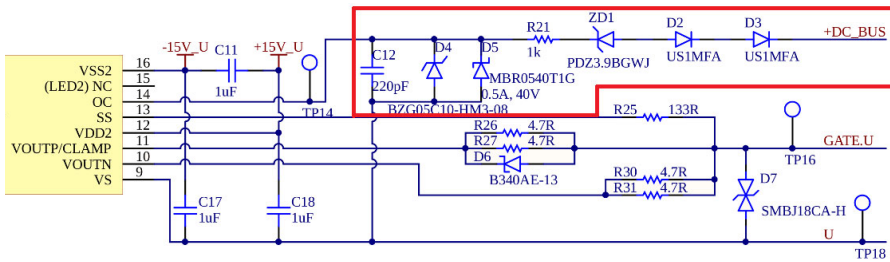
Figure 9: Isolated Gate Driver ACPL-352J High-Voltage Side



4.2.3 Protection Features

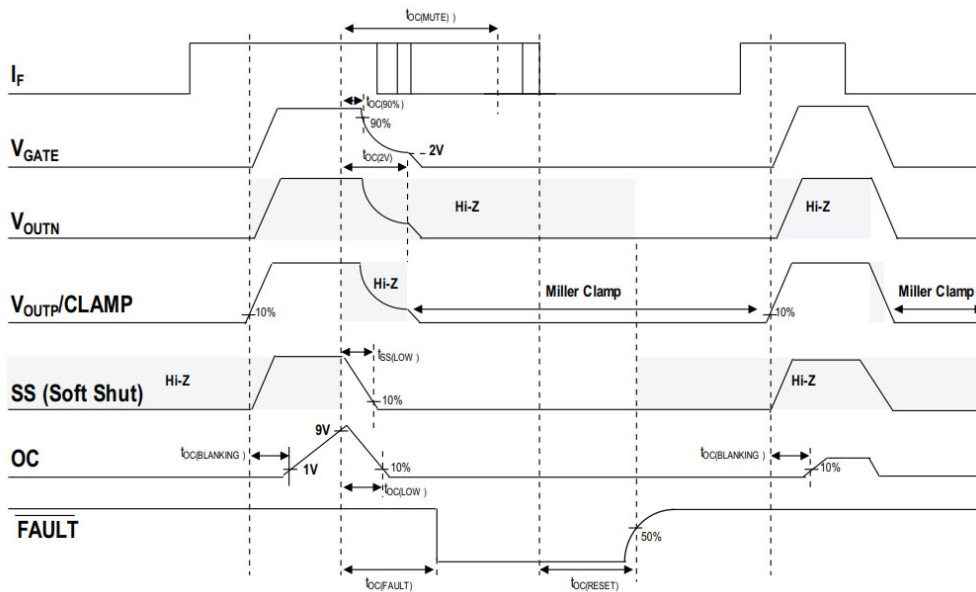
A typical power stage of the three-phase inverter is susceptible to several types of failures, related to the short circuit, which can potentially cause destruction of the IGBT. To prevent damage to the inverter, fault detection must be implemented to turn off the IGBTs in case of an overcurrent event. The secondary output stage of the ACPL352J (VOUT, CLAMP, OC, and SS) is controlled by the combination of VDD2, LED current (IF) and overcurrent (OC) conditions. For the details related to the logic truth table of these outputs, refer to the ACPL-352J data sheet. The driver provides an ideal solution combining local overcurrent detection (OC), soft shutdown (SS) with high-speed current output and high-voltage optical isolation. The OC part of the gate circuit is marked with a red rectangle in Figure 10.

Figure 10: DESAT Circuitry at ACPL-352J High-Voltage Side



Fault detection implemented in the ACPL-352J monitors the collector-emitter voltage of the IGBT and triggers a fault soft shutdown sequence (SS) if the collector-emitter voltage exceeds the predefined threshold. A soft turn-off gate discharge device slowly reduces the IGBT short circuit current to prevent damaging voltage spikes. Before the dissipated energy can reach destructive levels, the IGBT is turned off. During the off state of the IGBT, the fault detection circuitry is disabled to prevent false 'fault' signals. The OC fault detection circuitry must remain disabled for a short time period following the turn-on of the IGBT, to allow the collector voltage to fall below the OC threshold. This time period, called the OC blanking time, is controlled by the internal OC charge current, the OC voltage threshold, and the external OC capacitor. The nominal blanking time is calculated in terms of external capacitance, FAULT threshold voltage (V_{OC}), and DESAT charge current (I_{CHG}) in addition to an internal OC blanking time ($t_{OC(BLANKING)}$). Figure 11 shows a diagram describing the operation of the driver during an OC fault condition.

Figure 11: Circuit Behaviors during an Overcurrent Condition. The diagram is the same as in the ACPL-352J data sheet.



The OC terminal monitors the voltage between the collector and the emitter (V_{CE}) of the IGBT. When this voltage exceeds 9V, the output voltages (V_{OUTP} and V_{OUTN}) go to high impedance state and the SS pulls down the V_{GATE} at a slow rate adjustable using the resistor. When the gate voltage falls below $V_{EE} + 2V$, the Miller clamp turns on to clamp the IGBT gate to V_{EE} . After this event, the FAULT output goes low. When $t_{OC(MUTE)}$ expires, the LED input must be kept low for $t_{OC(RESET)}$ before the fault condition is cleared. Afterwards, the FAULT status returns to high. The output stage responds to the input only after the input fault condition has been cleared.

To isolate the collector from the gate driver circuit when the IGBT is off and to be able to adjust the sensed saturation voltage between the collector and the emitter, OC diodes (D4 and D5 in Figure 10) are added in the circuit. By changing the forward voltage value of the mentioned diodes, the user can modify threshold level of the saturation voltage. This configuration can be also changed by retaining only one diode and placing a 0Ω resistor in place for the other diode. By increasing the total forward voltage (the sum of the forward voltages of both diodes), the user can decrease the OC threshold voltage. When using two diodes instead of one, the same type of diodes must be used, and the blocking voltage rating of these diodes can be half of the maximum reverse voltage. Additionally, the OC threshold voltage is adjusted by adding a low-voltage Zener diode (ZD1 in Figure 10).

When IGBT is switching off, a reverse current flows for a short time, which prevents the diode from achieving its blocking capability until the charge in the junction is depleted. During this time, the positive voltage slope between the collector and the emitter results in current that tends to charge the blanking capacitor. The minimization of this current and the avoidance of false OC triggering are achieved with fast diodes. Aside from OC and Zener diodes in series, there is one more component that ensures the safety of the driver—a 1-kΩ resistor (R21 in Figure 10) in series with the previous components. This resistor limits the current caused by negative voltage spikes (generated by inductive loads or reverse recovery spikes of the free-wheeling diode) on the OC pin, thus preventing damage to the driver. To additionally prevent false fault signals caused by negative voltage spikes on the OC pin, connect the Zener and Schottky diode between the OC and the V_E pin.

In addition to the described protection mechanism during short circuit behavior, the status of the IGBT gate voltage is monitored by output pins VOUTP and VOUTN. The GFAULT feedback signal output goes low when the gate voltage does not correspond to the LED input logic. The status of the gate is checked after a minimum delay time t_{GFAULT} to allow enough time for the gate to charge or discharge to its final level. When the LED input logic is high, VOUTN is sensed to check if the gate voltage is higher than $V_{DD2} - 2V$ after a t_{GFAULT} delay. The GFAULT output goes low if the gate voltage is lower than $V_{DD2} - 2V$. Likewise, when the LED input logic is low, VOUTP is sensed to check if the gate voltage is lower than $V_{SS2} + 2V$. GFAULT output returns to high upon an input logic change or if the gate voltage manages to cross the threshold of $V_{DD2} - 2V$ or $V_{SS2} + 2V$. Because the VOUTP and CLAMP functions share the same pin, the gate voltage is continuously monitored by VOUTP whether it is in a high impedance state or a CLAMP state when the LED input logic is low.

4.2.4 Gate Resistor Consideration

The first step in choosing the appropriate gate resistor is to calculate its minimal value from the $I_{O(PEAK)}$ specification. The IGBT and the gate resistor can be analyzed as a simple RC circuit with a voltage supplied by the ACPL-352J.

$$R_G \geq \frac{V_{CC} - V_{EE}}{I_{O(PEAK)}} - R_{DS(MIN)}$$

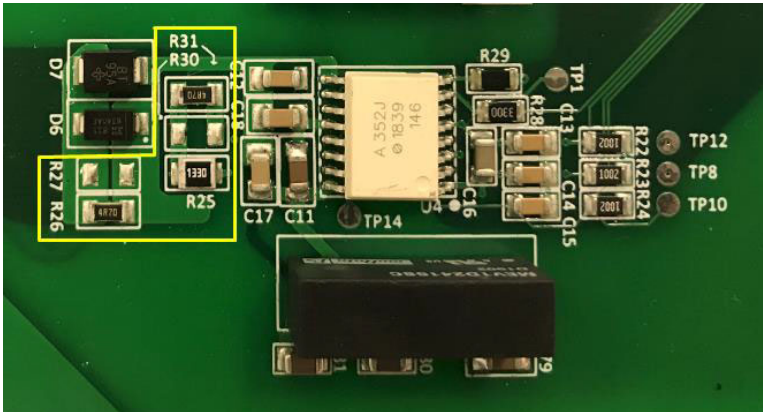
Note that $R_{DS(MIN)}$ can be different for high-side and low-side power switches. Therefore, calculations for both are necessary. This external gate resistor combined with an internal minimal turn-on resistance ensures that the output current does not exceed the device absolute maximum rating of 4A.

The next step in choosing the correct gate resistor is to check the power dissipation of the ACPL-352J gate driver. If the power dissipation is too high, the resistance of the gate resistor should be increased. For detailed instructions on choosing the gate resistor, refer to the ACPL-352J data sheet.

The final step in the turn-off gate resistor selection is ensuring that during turn-off, the transient at the maximal allowed collector current, IGBT collector-emitter voltage does not exceed the blocking voltage on the IGBT device. The criteria for the turn-on gate resistor are the maximal collector current peak, related to the reverse recovery of the opposite freewheeling diode. This peak must not exceed double the value of the nominal collector current.

To ensure the constraints described previously, the EB1200-352J comes with a 4.7Ω gate resistor for positive gating connected to VOUTP and with 4.7Ω for negative gating connected to VOUTN as a default assembled variant. In addition, evaluation board is designed to enable Broadcom customers to evaluate switching characteristics of the semiconductors by changing or combining turn-on/turn-off resistors (as described in [Section 4.2.2, Gate Driver Circuit: High-Voltage Side](#)). [Figure 12](#) shows the disposition of the gate resistors.

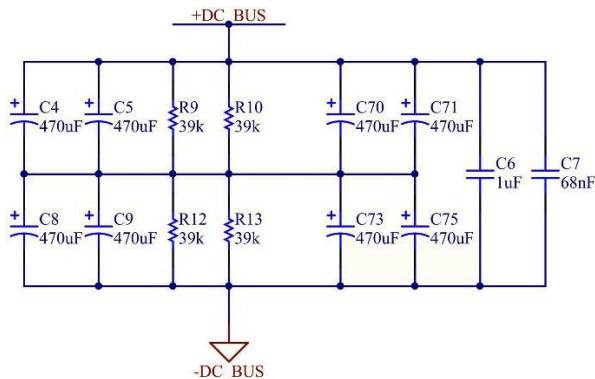
Figure 12: Disposition of the Gate Resistors



4.3 DC Bus and Discharge Resistors

The DC bus capacitor bank on the EB1200-352J consists of $4 \times 470\text{-}\mu\text{F}$, 450V electrolytic capacitors, two in series connection, a $1\text{-}\mu\text{F}$, 850V film capacitor, and a 68-nF , 1200V ceramic capacitor, as shown in [Figure 13](#). These components are added to the design to simplify the evaluation of the gate driver and the semiconductor switching characteristics and to provide high quality DC bus for full inverter utilization. In addition, board is designed to support four more electrolytic capacitors to enable easy estimation of the inverter characteristics on demanding loads. For an appropriate voltage sharing on series-connected electrolytic capacitors and safety discharging purposes, two ceramic $39\text{-k}\Omega$ resistors are connected in parallel to each electrolytic capacitor ([Figure 13](#)).

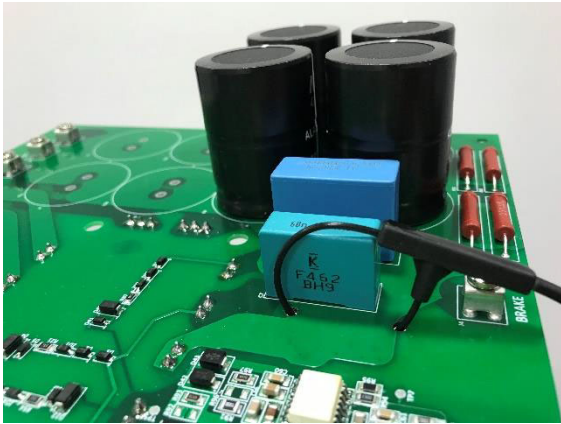
Figure 13: DC Bus Capacitor Bank with Discharge Resistors. Capacitors C70, C71, C73, and C75 are not populated.



4.4 IGBT Current Measurement

To enable users to obtain a semiconductor current waveform during switching instances, the board is designed with two dedicated holes mechanically positioned to cover the traces connecting the low-side emitters and the negative potential of the DC bus capacitors, as shown in [Figure 14](#). Holes with $\phi = 5$ mm enable using a Rogowski current probe for current measurement purposes.

Figure 14: Dedicated Holes Enable Users to Measure the Current of the Single IGBT



4.5 Temperature Measurement

The EB1200-352J contains the temperature measurement circuit shown in [Figure 15](#). The voltage drop on the PIM's negative temperature coefficient (NTC) thermistor is amplified using an ACPL-C87A isolated linear optocoupler and additionally buffered using an operation amplifier. [Figure 16](#) shows the typical temperature response of the measurement circuit. Note that the output voltage range can be adjusted by changing the value of the feedback resistor R104 as well as resistors R102 and R103 in the amplifier circuit.

Figure 15: EB1200-352J Isolated Temperature Measurement Circuit

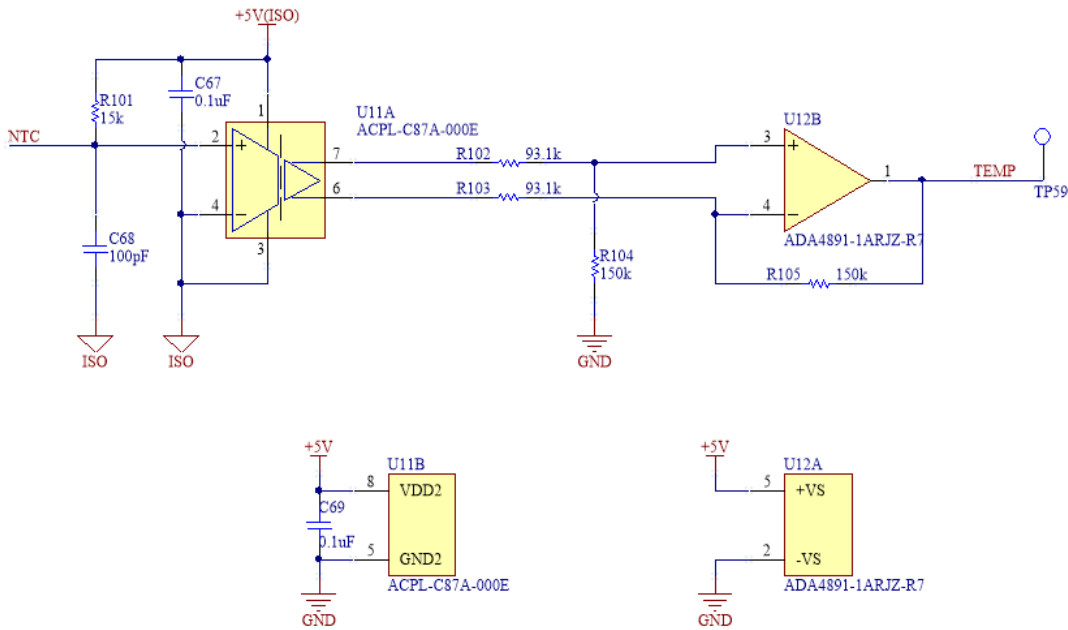
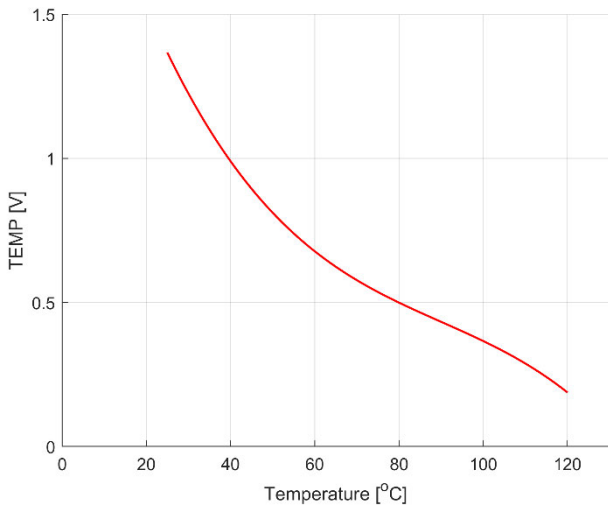


Figure 16: Typical Temperature Measurement Characteristic



Chapter 5: Setup

WARNING! The EB1200-352J board is designed to work with 600V and thus requires that all safety precautions and national accident prevention rules must be undertaken and observed by skilled technical personnel, related to a board installation, use, and maintenance. There is a danger of serious injury and damage of property if the board is improperly used or installed. It is strongly recommended that a system aimed to supply the evaluation board is equipped with control and protection devices, in agreement with the applicable safety standards.

ATTENTION: Signals dedicated for high-side and low-side drivers, in one inverter leg, must have proper dead-time. The board itself does not provide dead-time generation. The recommended minimal dead-time is 5 μ s.

5.1 Installation of the EB1200-352J

Before evaluating the board, perform these installation steps:

1. Before any installation, make a visual inspection of the board to make sure it contains all components assembled except the PIM module. See [Section A.3, BOM](#), for the list of components. The EB1200-352J, by default, does not contain an assembled PIM module to avoid damage of the module and the evaluation board during transport, as well as to provide the customer an option to use other modules with the same footprint.
2. Ground the board. Connect the –DC_BUS terminal to earth potential.
3. Connect the signal connector. The PWM signals as well as the ACPL-352J output fault signals can be connected to any control board with 5V/3.3V logic.
4. Connect a 24V external power supply. The EB1200-352J requests a 24V external power supply to enable 5V digital operations and a ± 15 V gate driver high-voltage side power supply. Although the polarity is marked, the board is reverse protected at the terminals of 24 V external supply.
5. Turn on power to the board by performing these steps:
 - Case 1, with DC voltage:
 - a. Connect the DC power supply on terminals +DC_BUS and –DC_BUS.
 - Case 2, with three-phase AC voltage:
 - a. Use terminals N_REC and –DC_BUS to connect the external pre-charge circuit.

NOTE: Precautions: Due to technical requirements, the evaluation board does not comprise a pre-charge circuit that enables soft DC bus charging. In the case that the three-phase autotransformer is not used, an external pre-charge circuit must be installed to avoid DC bus capacitor failure, which would cause injury and damage to property.

- b. Use terminals L1, L2, and L3 to connect the three-phase AC power supply.

ATTENTION: The maximum allowed input AC voltage is 480V.

5.2 Evaluation of the EB1200-352J

The EB1200-352J enables users to evaluate the following items:

- ACPL-352J driver features
- ACPL-C87A voltage sensor features
- Switching characteristics of the semiconductors within the PIM module
- Inverter basic features

To evaluate semiconductor switching characteristics with the EB1200-352J, perform a double pulse test, and measure the transients related to the semiconductor and the ACPL-352J driver circuit.

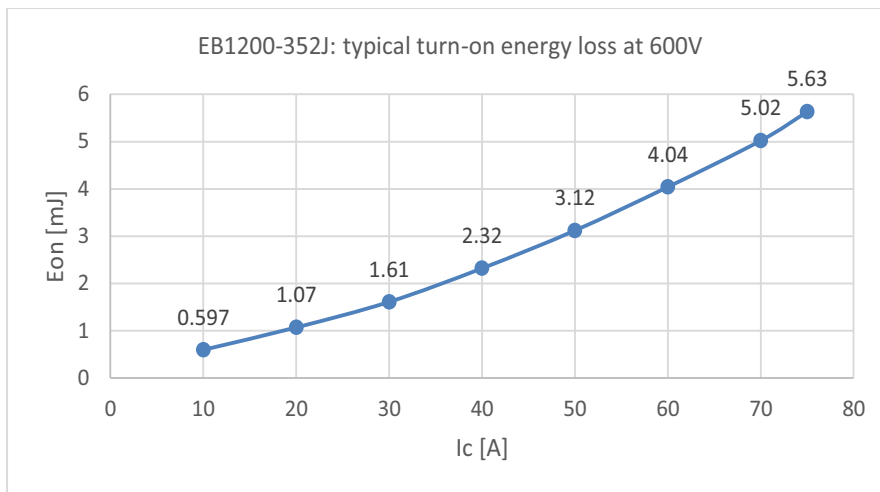
Chapter 6: Typical Switching and DESAT Protection Characteristics

6.1 Typical Switching Losses

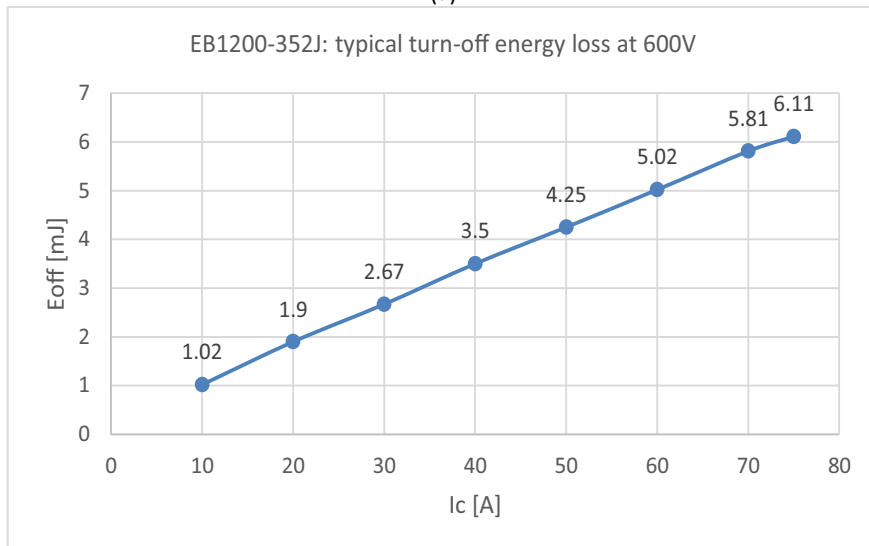
Because the EB1200-352J has integrated a DC bus capacitor bank, the worst-case commutation inductance (measured for the switch with the longest path to the DC bus capacitors) is a constant 67 nH and does not vary from the setup used to characterize switching characteristic.

As an example, [Figure 17](#) shows the obtained turn-on and turn-off losses at 25°C for PIM FP75R06KT4.

Figure 17: (a) Turn-On (E_{on}) and (b) Turn-Off (E_{off}) Switching Energy



(a)



(b)

6.2 Typical Switching Waveforms

Switching waveforms during hard switching of the semiconductors are measured with an oscilloscope using the standard double-pulse test procedure. Figure 18 shows the turn-on switching transient, while in Figure 19, the turn-off switching transient is depicted.

Figure 18: Oscilloscope Screenshot of Turn-On Transient, $V_{dc} = 600V$, $I_c = 75A$, CH1 (Yellow) V_{ce} , CH3 (Blue) V_{ge} , CH4 (Green) V_{dc} , F6 (Red) I_c

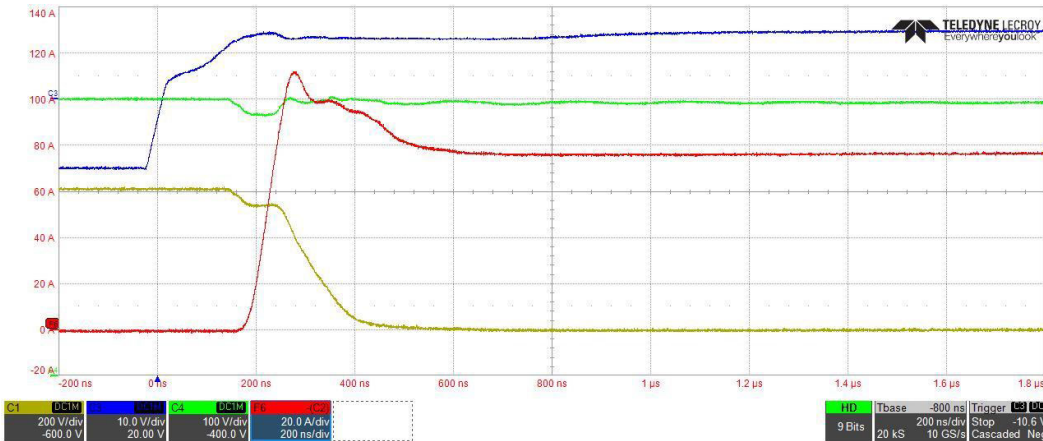
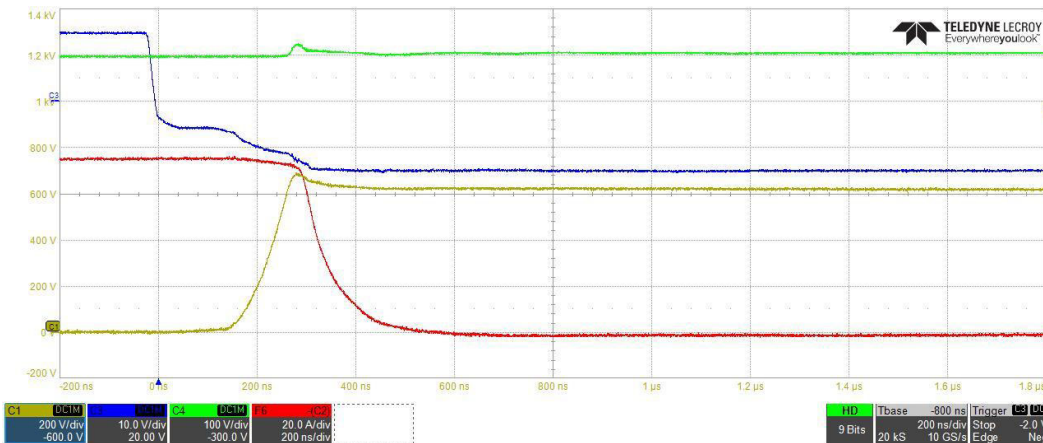


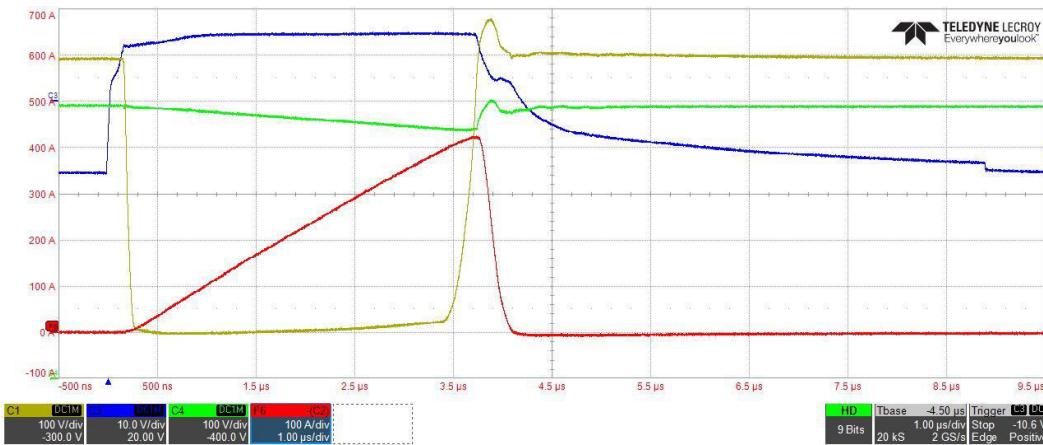
Figure 19: Oscilloscope Screenshot of Turn-Off Transient, $V_{dc} = 600V$, $I_c = 75A$, CH1 (Yellow) V_{ce} , CH3 (Blue) V_{ge} , CH4 (Green) V_{dc} , F6 (Red) I_c



6.3 Typical DESAT Protection Performance

The functioning of the DESAT protection is obtained by performing the direct short circuit on one of the bridge legs. Figure 20 shows the results of this measurement.

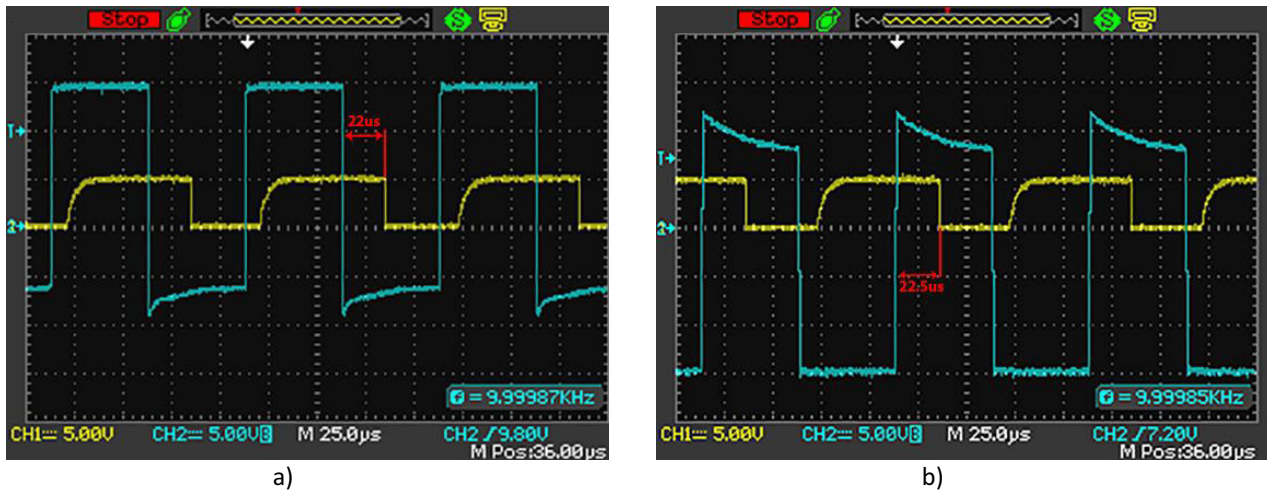
Figure 20: Measurement Results from DESAT Detection, Direct Short Circuit at $V_{dc} = 600V$, CH1 (Yellow) V_{ce} , CH3 (Blue) V_{ge} , CH4 (Green) V_{dc} , F6 (Red) I_c



6.4 Typical GFAULT Performance

Typical GFAULT detection in condition when the gate voltage is below the GFAULT thresholds is shown in Figure 21 in cases a) IGBT turn-on and b) IGBT turn-off.

Figure 21: Measurement Results from GFAULT Detection, CH1(Yellow) GFAULT, CH2(Blue) V_{ge}



Appendix A: Schematics, Layout, and BOM

This appendix includes full schematics, layout, and bill of materials of the EB1200-352J. This information helps customers to modify, copy, and qualify the design for production, according to specific requirements.

A.1 Schematics

Figure 22: EB1200-352J Top-Level Sheet

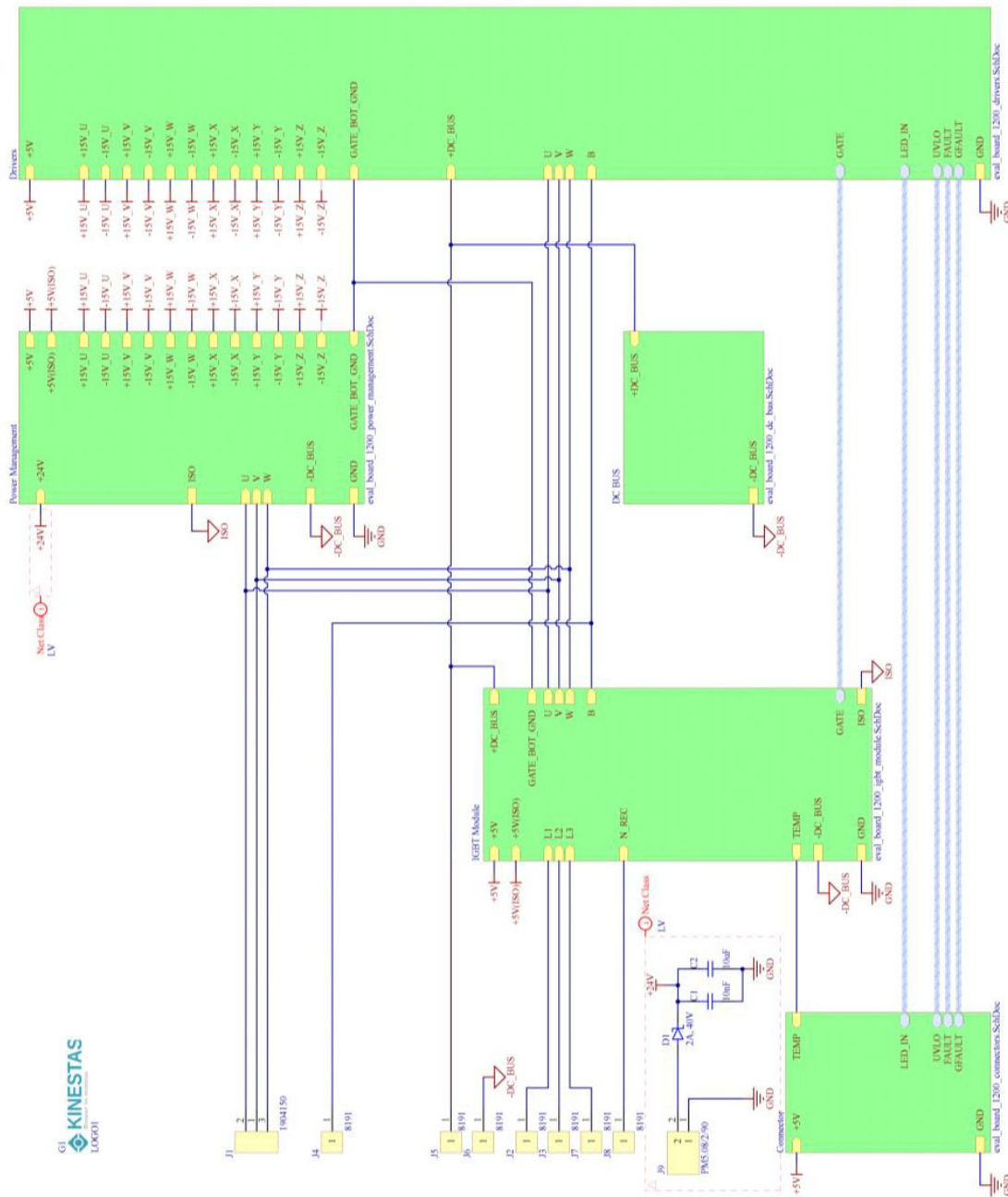


Figure 23: EB1200-352J, Sheet 1, Connector

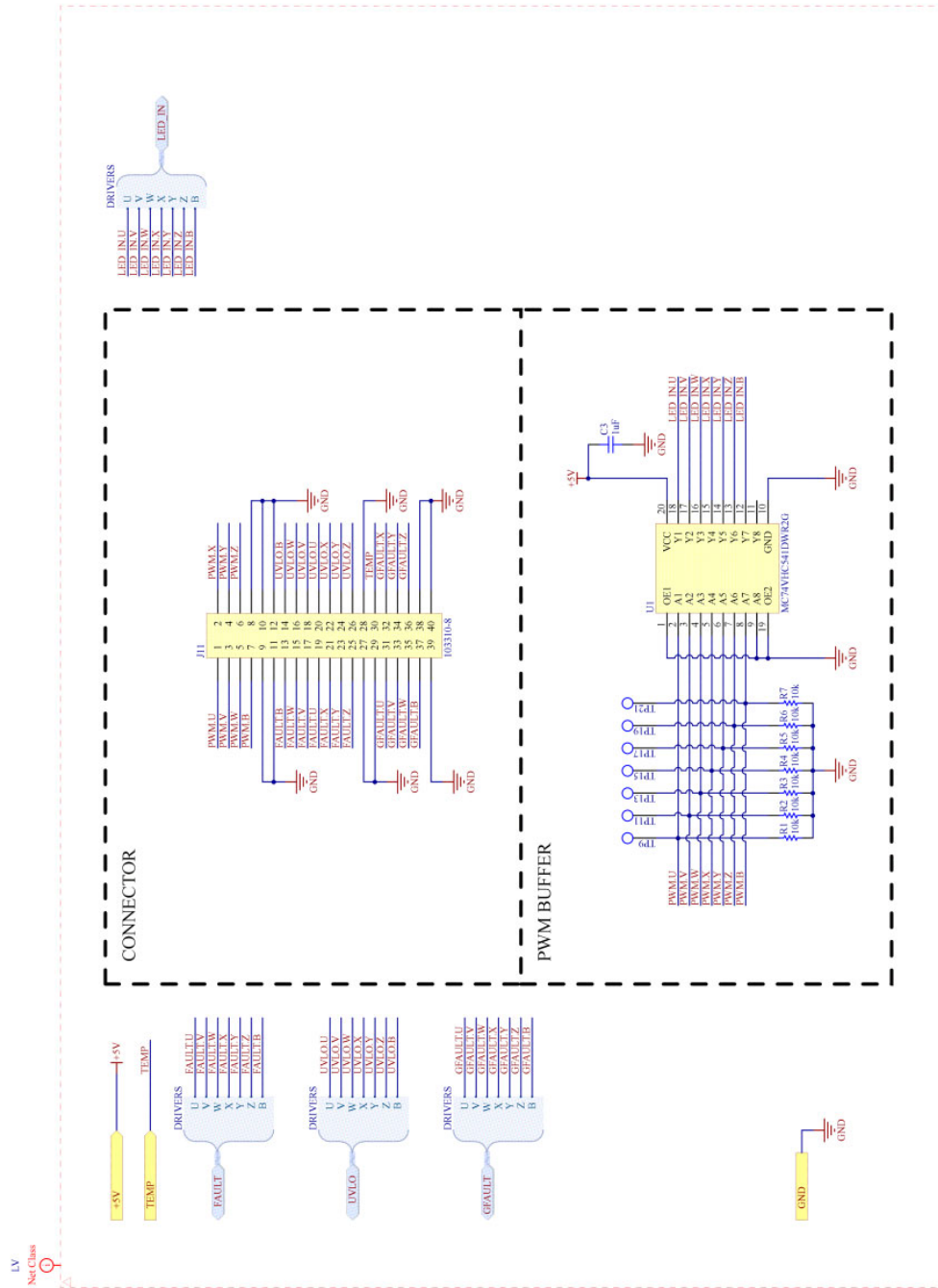


Figure 24: EB1200-352J, Sheet 2, DC Bus

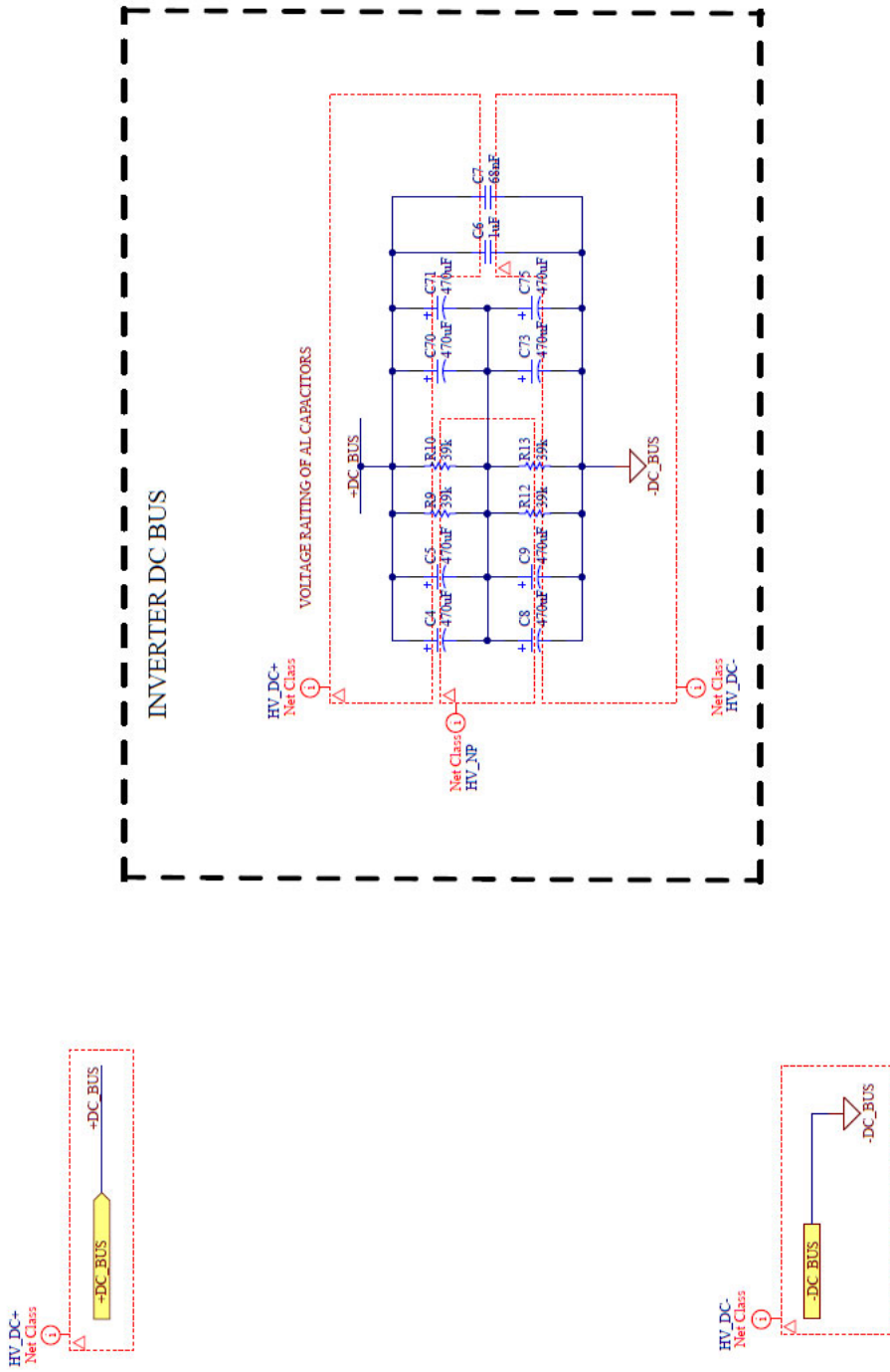


Figure 25: EB1200-352J, Sheet 3, Drivers

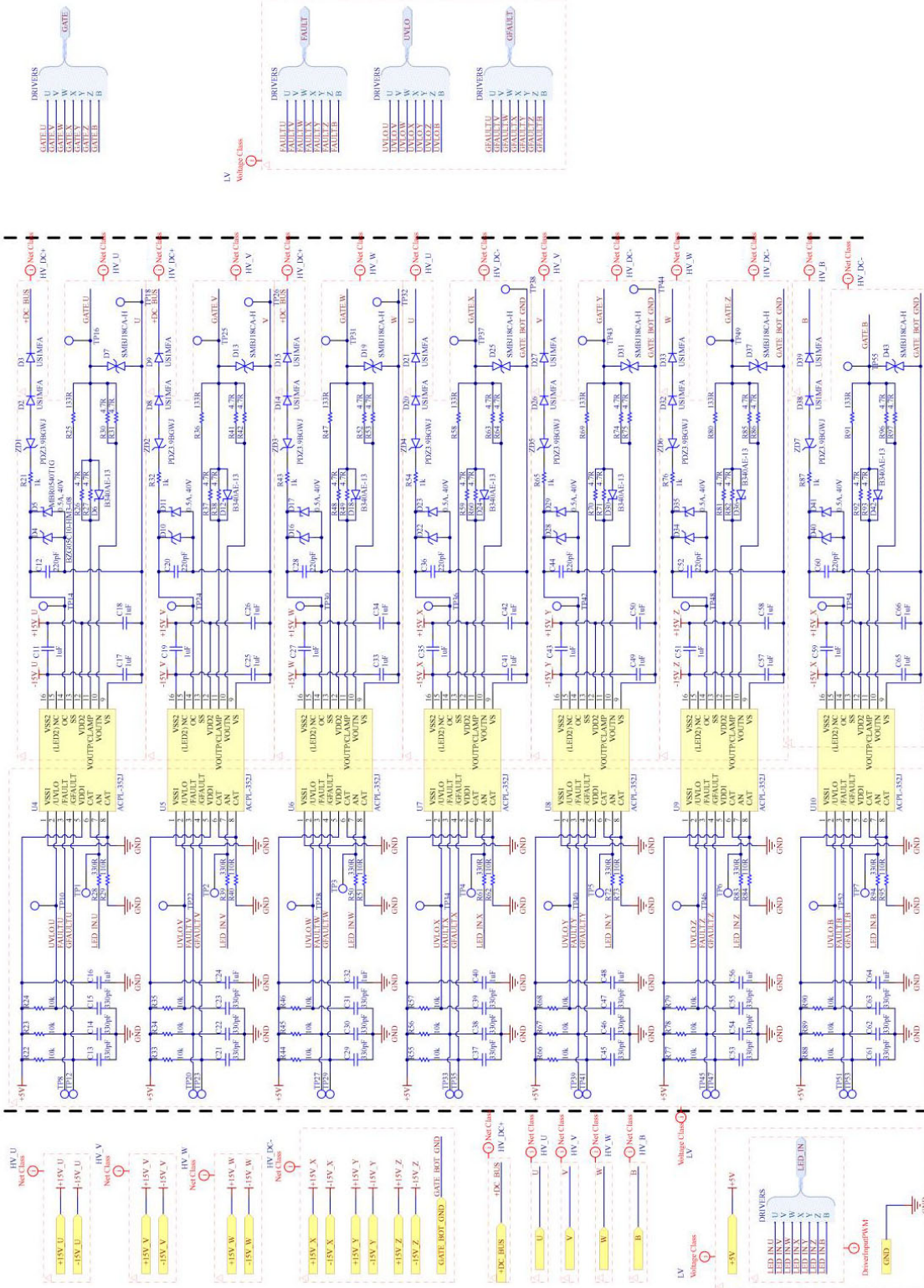


Figure 26: EB1200-352J, Sheet 4, IGBT Module

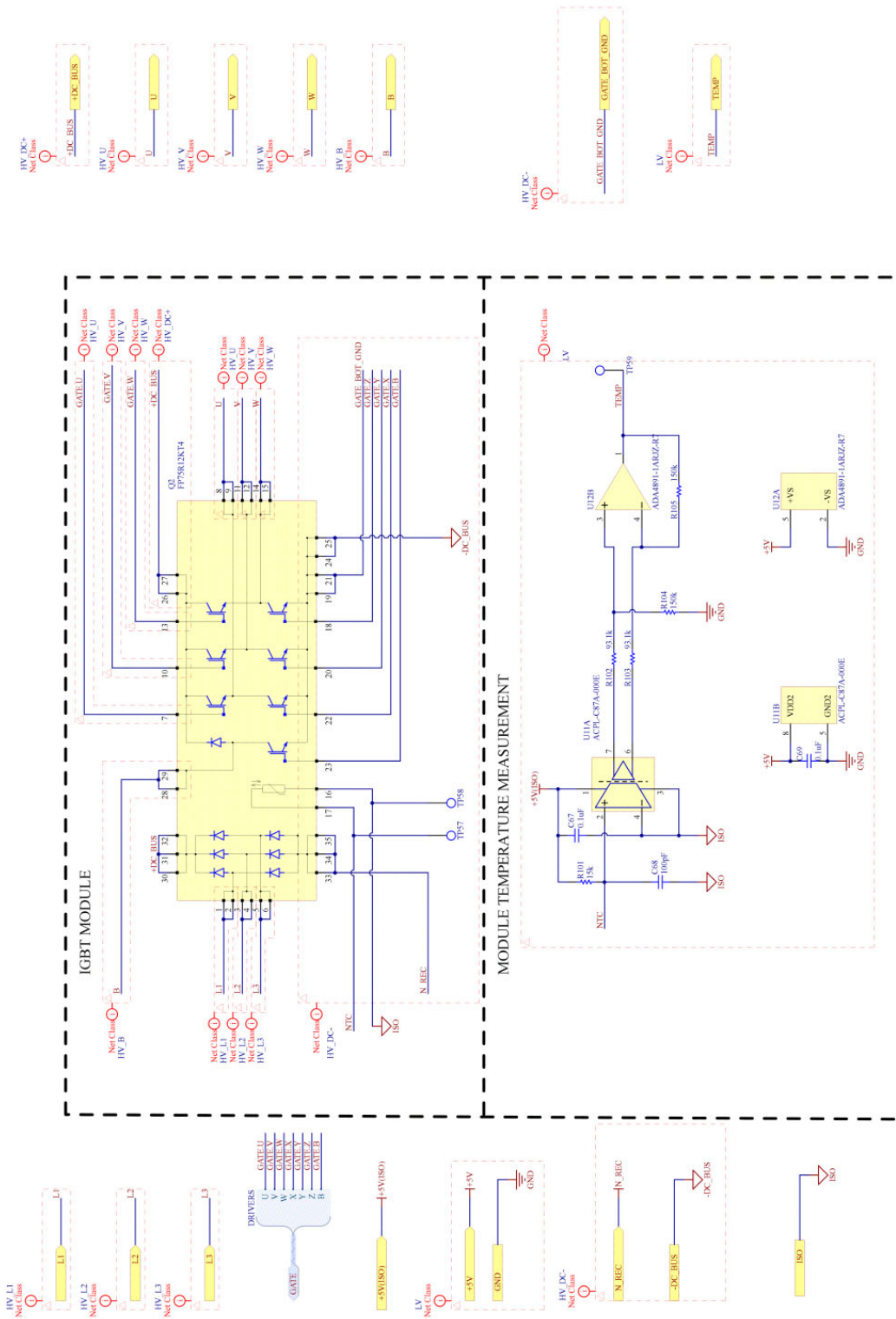
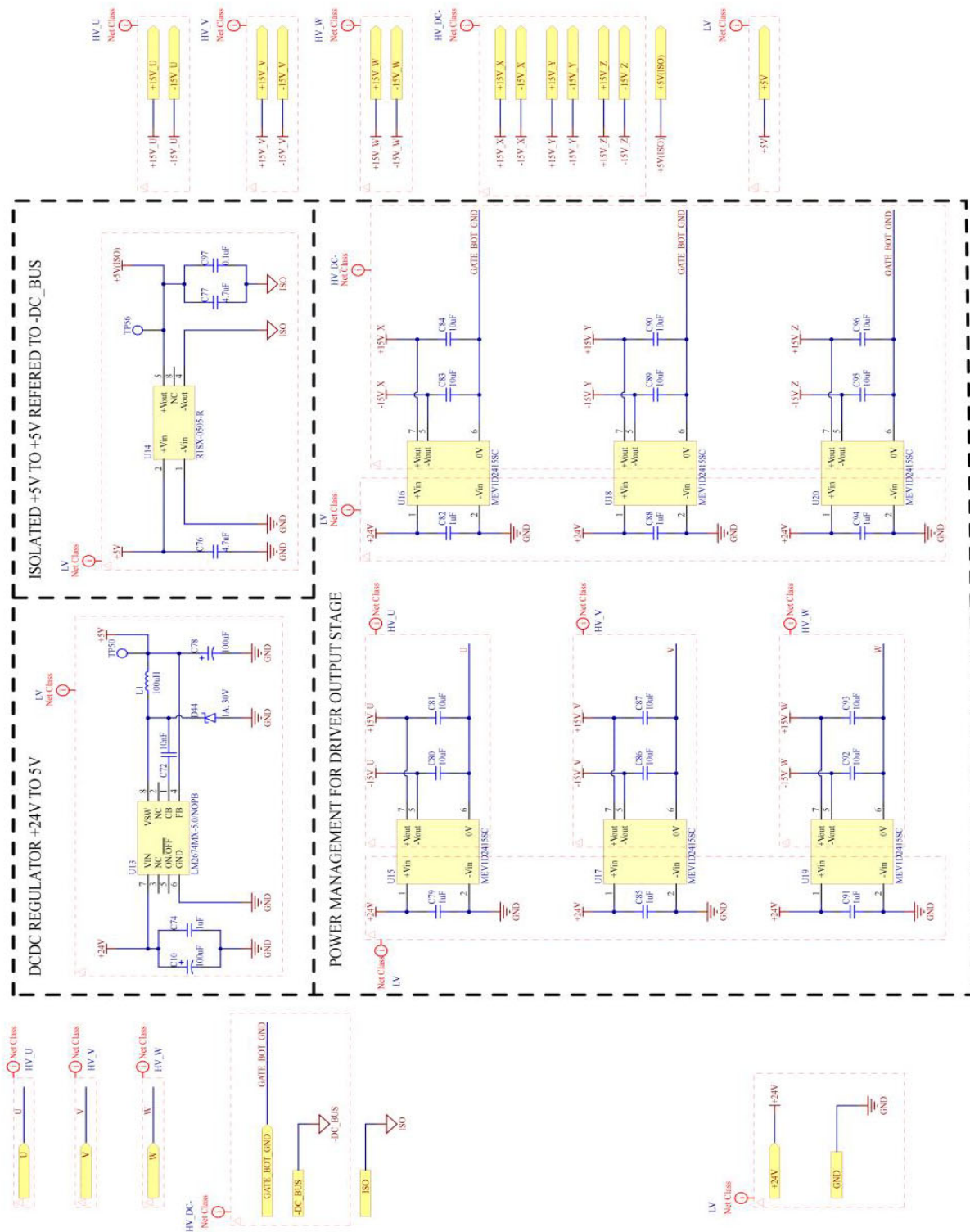


Figure 27: EB1200-352J, Sheet 5, Power Management



A.2 Layout

Figure 28: EB1200-352J, Assembly Drawing

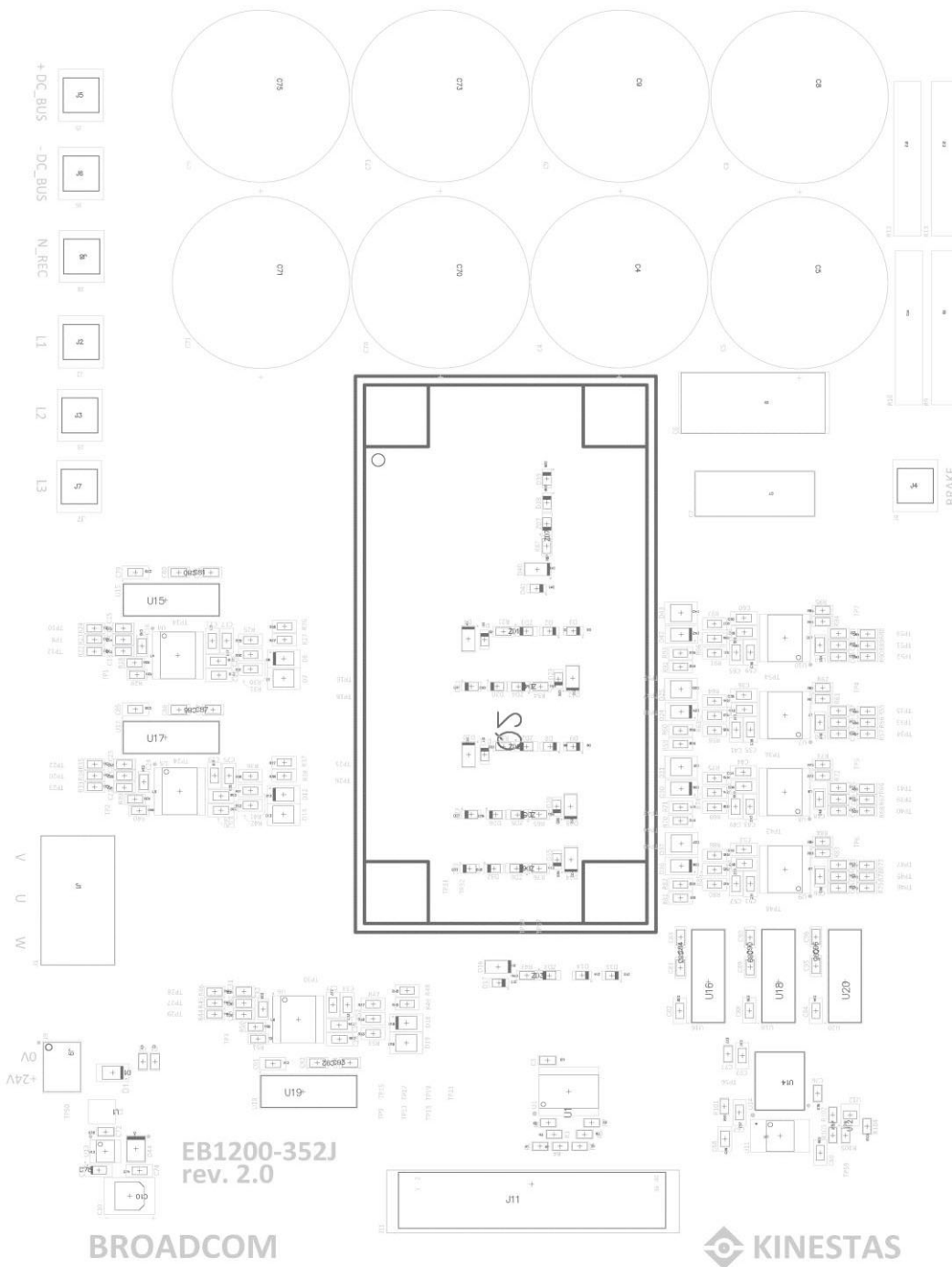


Figure 29: EB1200-352J, Top Layer

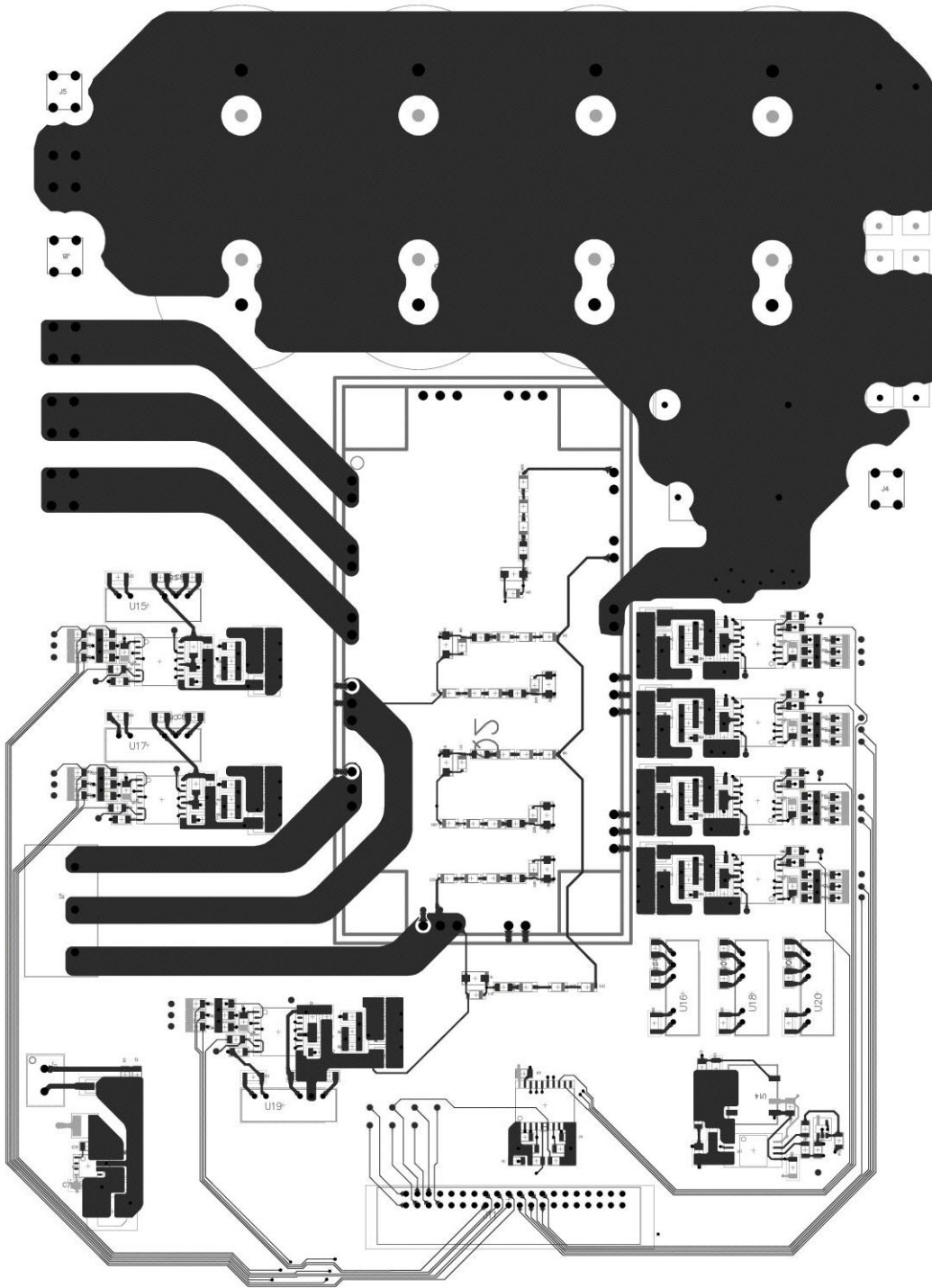


Figure 30: EB1200-352J, Signal Layer 1

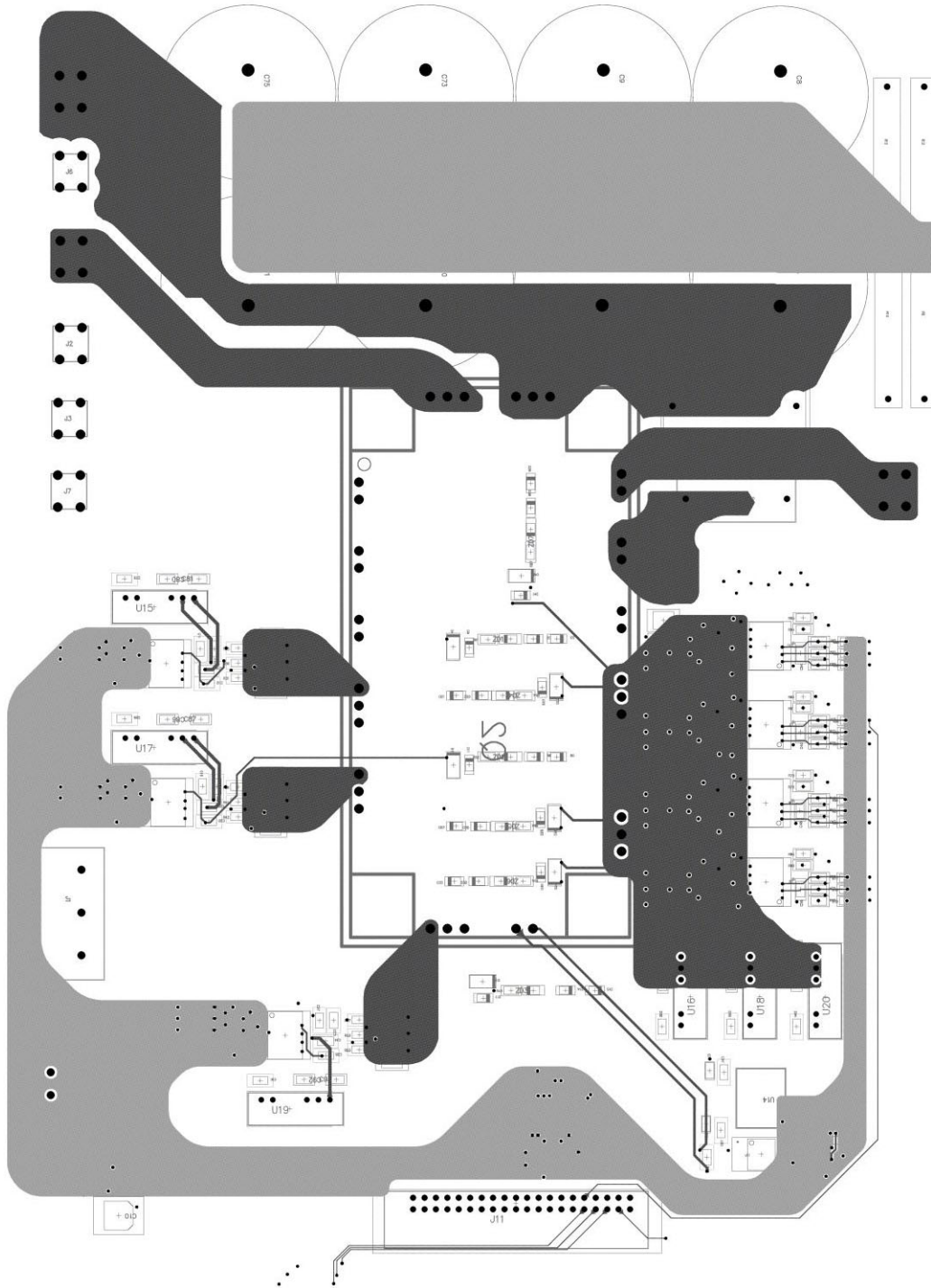


Figure 31: EB1200-352J, Signal Layer 2

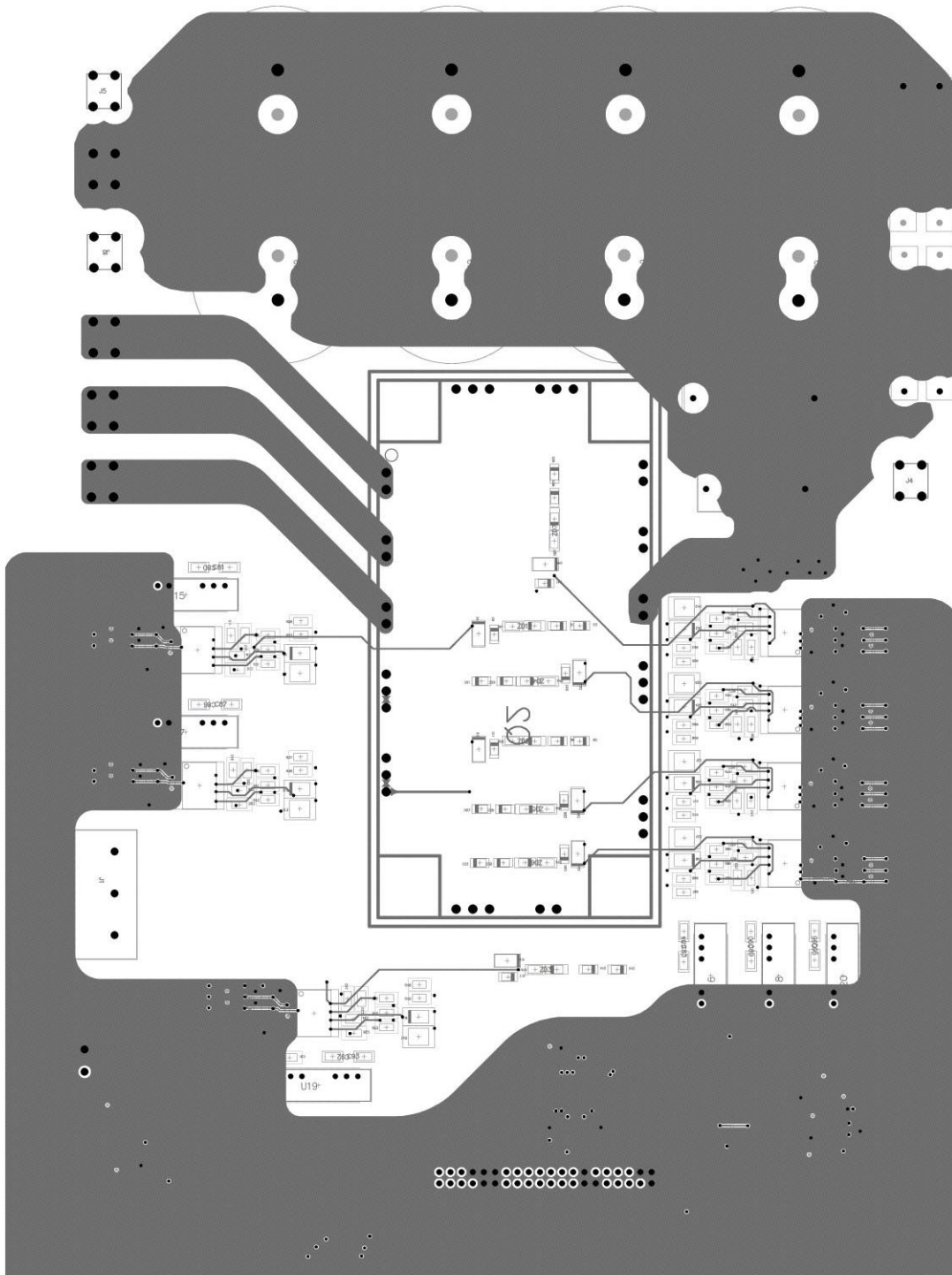
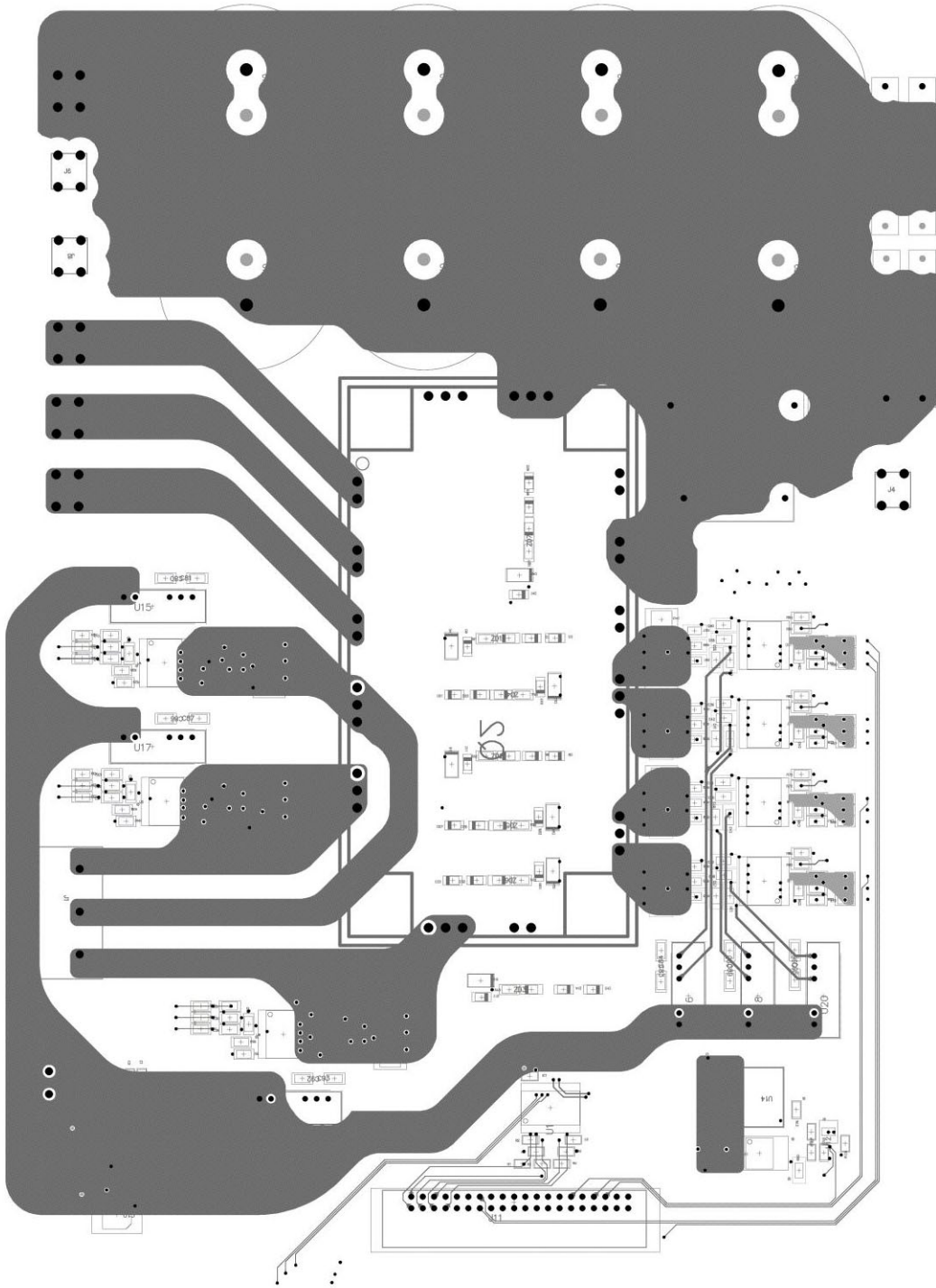


Figure 32: EB1200-352J, Bottom Layer



A.3 BOM

Table 5 shows the bill of materials for the EB1200-352J.

Table 5: Bill of Materials for the EB1200-352J

Designator	Manufacturer Part Number
C1, C72	VJ1206Y103JXAMC
C2	GMK316BJ106KL-T
C3, C16, C24, C32, C40, C48, C56, C64	VJ1206Y105MXJTW1BC
C4, C5, C8, C9, C70, C71, C73, C75	ALA7DA471DE500
C6	B32674D8105K
C7	F462DO683M1K6Z
C10	
C11, C19, C27, C35, C43, C51, C59, C74, C79, C82, C85, C88, C91, C94	CC1206ZRY5V9BB105
C12, C20, C28, C36, C44, C52, C60	885012208071
C13, C14, C15, C21, C22, C23, C29, C30, C31, C37, C38, C39, C45, C46, C47, C53, C54, C55, C61, C62, C63	VJ1206A331KXQPW1BC
C17, C18, C25, C26, C33, C34, C41, C42, C49, C50, C57, C58, C65, C66	GMK316BJ105MLHT
C67, C69, C97	VJ1206Y104JXQCW1BC
C68	VJ1206A101JXQCW1BC
C76, C77	885012208017
C78	TLJA107M010R1400
C80, C81, C83, C84, C86, C87, C89, C90, C92, C93, C95, C96	TMK316BJ106KL-T
D1	B240AE-13
D2, D3, D8, D9, D14, D15, D20, D21, D26, D27, D32, D33, D38, D39	US1MFA
D4, D10, D16, D22, D28, D34, D40	BZG05C10-HM3-08
D5, D11, D17, D23, D29, D35, D41	MBR0540T1G
D6, D12, D18, D24, D30, D36, D42	B340AE-13
D7, D13, D19, D25, D31, D37, D43	SMBJ18CAHE3/52
D44	MBRS130LT3G
J1	MKDS5HV/3-9,52
J2, J3, J4, J5, J6, J7, J8	8191
J9	PM5.08/2/90
J11	103310-8
L1	VLS5045EX-101M
Q2	FP75R12KT4_B11
R1, R2, R3, R4, R5, R6, R7, R22, R23, R24, R33, R34, R35, R44, R45, R46, R55, R56, R57, R66, R67, R68, R77, R78, R79, R88, R89, R90	CRCW120610K0FKEAC
R9, R10, R12, R13	HPC2C393K
R21, R32, R43, R54, R65, R76, R87	CRCW12061K00JNEA
R25, R36, R47, R58, R69, R80, R91	ESR18EZPF1330
R26, R27, R30, R31, R37, R38, R41, R42, R48, R49, R52, R53, R59, R60, R63, R64, R70, R71, R74, R75, R81, R82, R85, R86, R92, R93, R96, R97	ESR18EZPF4R70
R28, R39, R50, R61, R72, R83, R94	CRCW1206330RFKEA
R29, R40, R51, R62, R73, R84, R95	CRCW1206110RFKEA
R101	RCG120615K0FKEA

Table 5: Bill of Materials for the EB1200-352J (Continued)

Designator	Manufacturer Part Number
R102, R103	CRCW120693K1FKEA
R104, R105	CRCW1206150KFKEA
U1	MC74VHC541DWR2G
U4, U5, U6, U7, U8, U9, U10	ACPL-352J-000E
U11	ACPL-C87A-000E
U12	ADA4891-1ARJZ-R7
U13	LM2674MX-5.0/NOPB
U14	R1SX-0505-R
U15, U16, U17, U18, U19, U20	MEV1D2415SC
ZD1, ZD2, ZD3, ZD4, ZD5, ZD6, ZD7	PDZ3.9BGWJ

A.4 Disclaimer

THIS APPLICATION NOTE CONTAINS INFORMATION THAT SHOULD SERVE ONLY AS A FIRST STEP FOR EVALUATION AND IMPLEMENTATION OF THE BROADCOM INC. TECHNOLOGIES. KINESTAS DOO DOES NOT TAKE RESPONSIBILITY FOR USING AND IMPLEMENTING BROADCOM TECHNOLOGIES IN OTHER DESIGNS.

Revision History

Version 1.0, October 3, 2019

- Initial release of the document.

